November 19th, 2025

Fault Injection – Keynote 2

BITFLIP Conference

Fault Injection
Keynote 2

November 19th, 2025
13:30

Le Refectoire

Jean-Max DUTERTRE

Professor, Mines Saint-Etienne

Monitoring Fault Injection Attacks with Sensors Lessons Learned

Equipe Commune Systèmes et Architectures Sécurisées
Mines Saint-Etienne, CEA, Leti, Centre CMP
13541 Gardanne FRANCE

Context – Hardware security

- Hardware security (ICs) – hardware attacks
- Secure HW: integrated circuits implementing security features
  - ✓ MCU/SoC with hardware cryptographic accelerator
  - ✓ Memory readback protection (IP & user data protection)

- Fault Injections Attacks (FIA)
  - ✓ Active/Perturbation attacks

  Attack objectives:
  - ✓ Information leakage (DFA) → secret key extraction
  - ✓ Control flow attacks (e.g., test inversion → memory extraction)

Context – Fault Injection Attack example

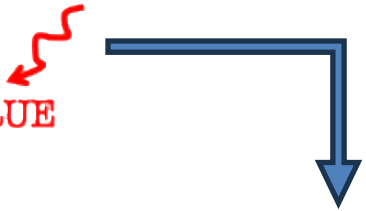
- Control Flow attack on a password verification routine
  - ✓ Test inversion through instr. modification / data corruption

```
If passwd equal to ref_passwd then
        access = TRUE
Else
        access = TRUE
End
```

Applied stress
→ FIA

Context – Monitoring FIA with sensors

```
If passwd equal to ref_passwd then
        access = TRUE
Else
        access = TRUE
End
```



Fault induced through the application of a **stress**

→ can be monitored and detected using **sensors**

- This talk
  - ✓ Monitoring FIA with digital sensors
  - ✓ Sensor principles
  - ✓ FIA mechanisms
  - ✓ Lessons learned designing and testing various sensors
    why many fail and others succeed

Monitoring FIA with Sensors – Lessons Learned

- Monitoring FIA with digital sensors – basics/principles

- Fault Injection Attacks
- EMFI detection sensors
- LFI detection sensors
- Conclusion

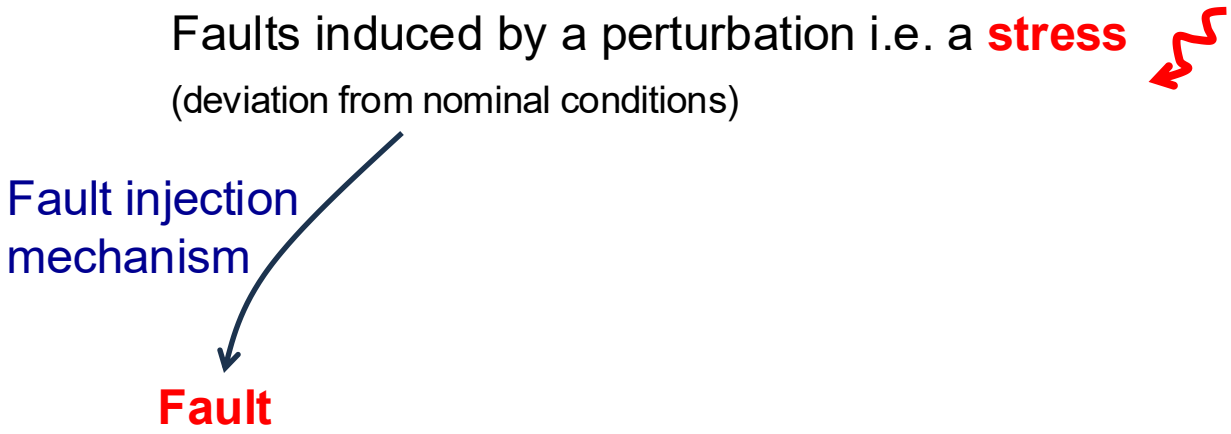
Monitoring FIA with digital sensors – basics/principles

- Digital sensors built from digital gates
  - ✓ Easier to design and to adapt to various technology nodes and manufacturers
  - ✓ Integration into ASIC and FPGA
  - ✓ Digital but based on analog mechanisms

- Analog sensors: custom analog design
  - ✓ Not addressed in this talk …
  - ✓ … not because they are less efficient but because not the speaker's expertise

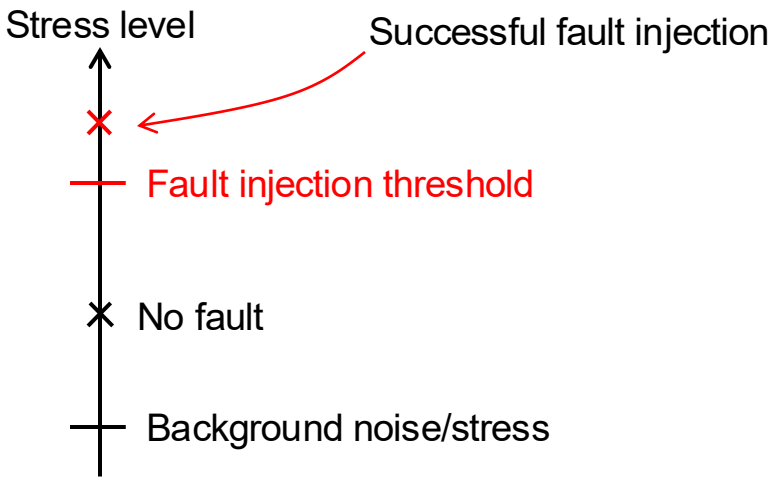
Monitoring FIA with digital sensors – basics/principles

- Detection principle → monitoring the applied stress



Monitoring FIA with digital sensors – basics/principles

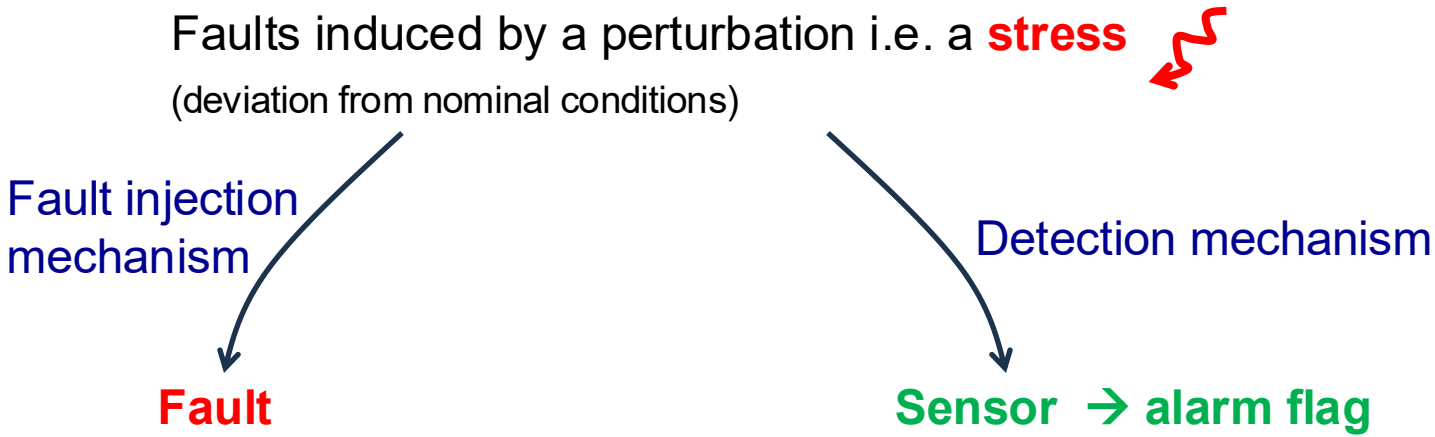
- Fault injection depends on the level of applied stress



⇨ A certain level of stress has to be reached: Fault injection threshold

Monitoring FIA with digital sensors – basics/principles

- Detection principle → monitoring the applied stress

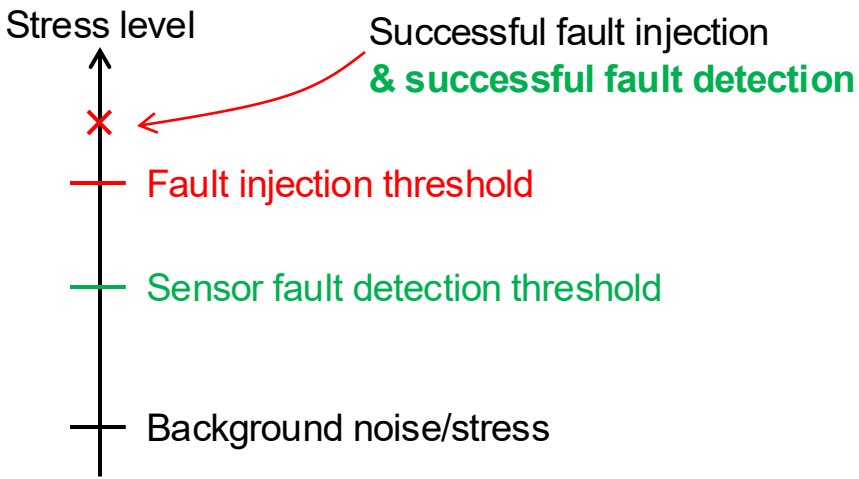


Main principle: detect the applied stress and raise an alarm flag

! a security policy has then to be applied, a sensor by itself is not a countermeasure …
(discussion out of the scope of this talk)

Monitoring FIA with digital sensors – basics/principles

- Sensor detection threshold vs fault injection threshold



- Setting the detection threshold below the fault threshold ensures an efficient detection of FIA

Monitoring FIA with digital sensors – basics/principles

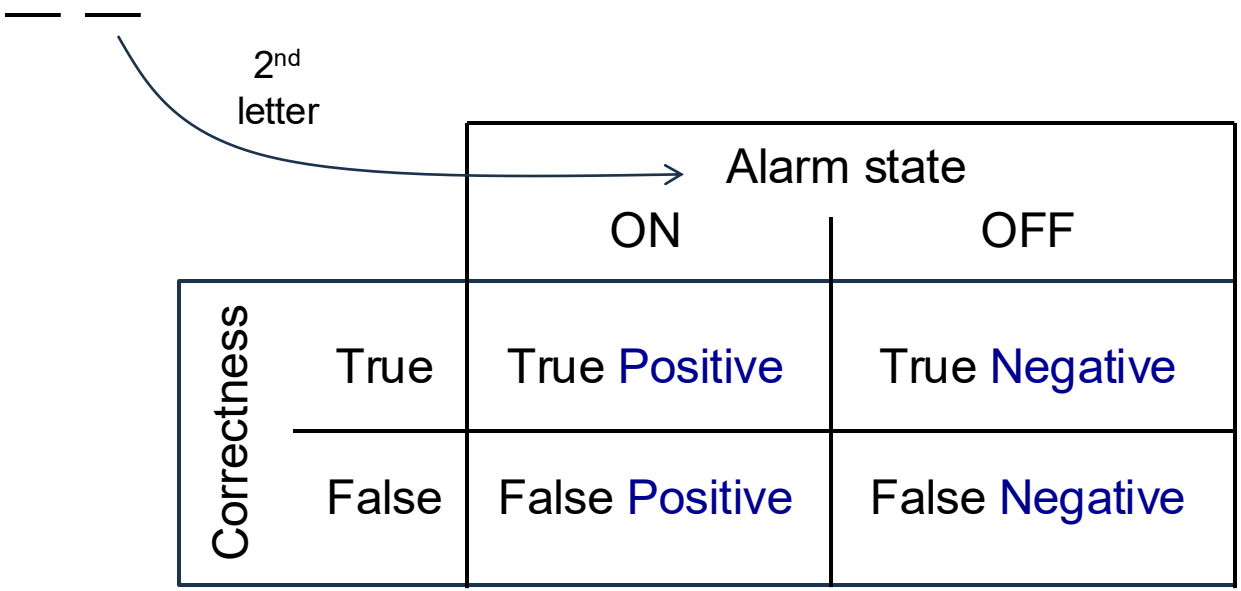
- Sensor design and evaluation metrics

- 2-step process
  - ✓ Sensor design, based on a detection mechanism (addressed later)
  - ✓ Sensor evaluation → on experimental basis

- Metrics
  - ✓ Type of monitored stress (Voltage, Temperature, Frequency, EMFI, LFI sensors)
  - ✓ Size
  - ✓ Power consumption
  - ✓ Latency
  - ✓ Detection threshold & area
  - ✓ Efficiency → sensor's response to be tested experimentally

Monitoring FIA with digital sensors – basics/principles

- Sensor response classification → 2-letter code TP/TN/FP/FN



Monitoring FIA with digital sensors – basics/principles

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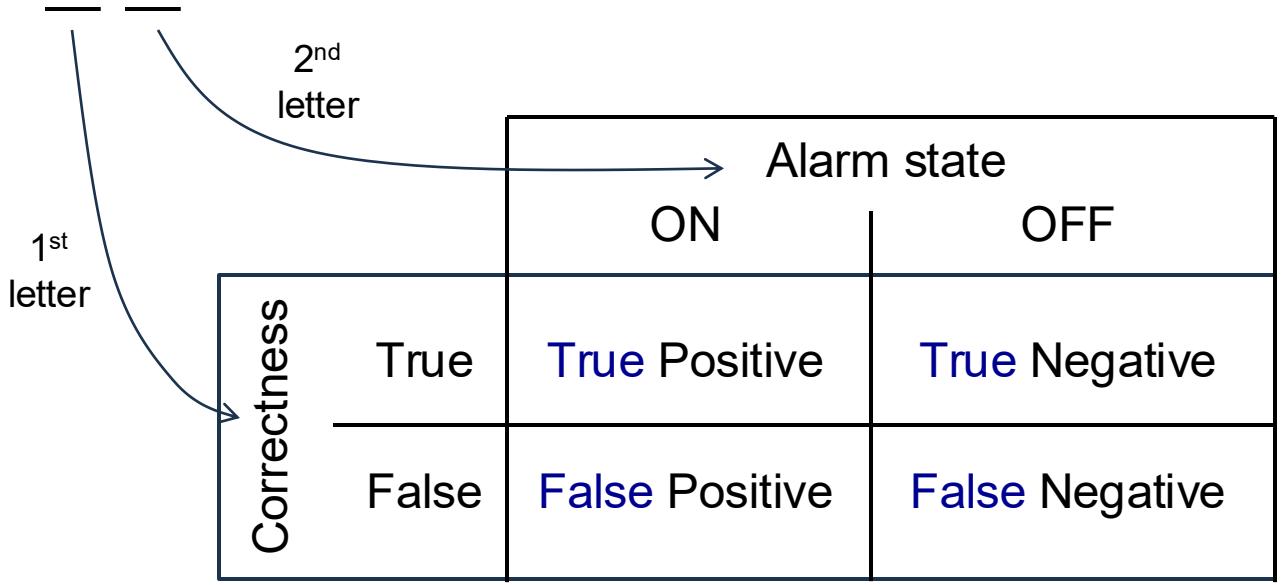
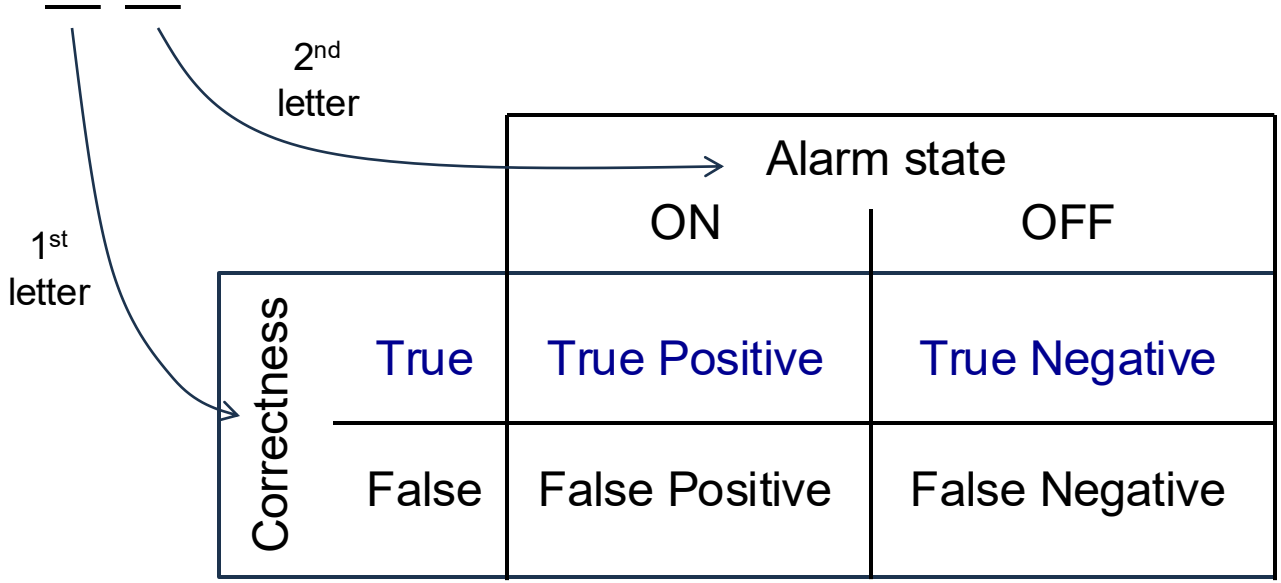


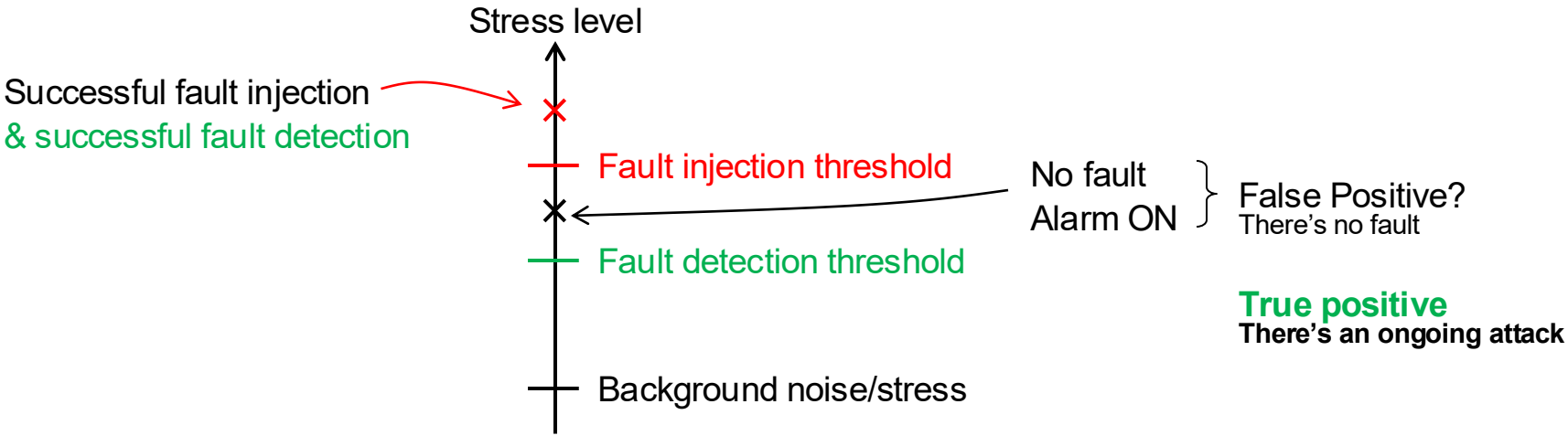
Sensor response classification

- Two ideal cases: True Positive & True Negative



Sensor response classification

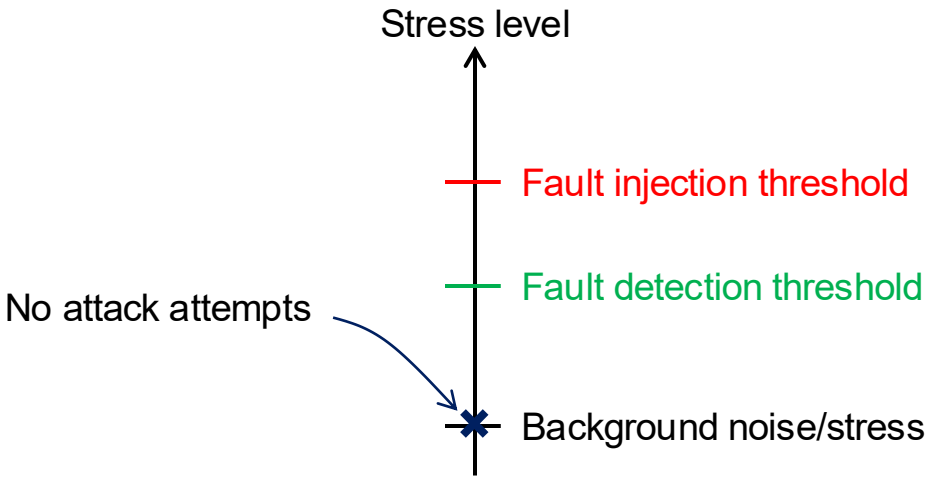
- Definition of a True Positive



⇨ FIA sensor = stress/attack detector, not a fault detector (based on information redundancy)

Sensor response classification

- True Negative case: presence of a background noise or stress

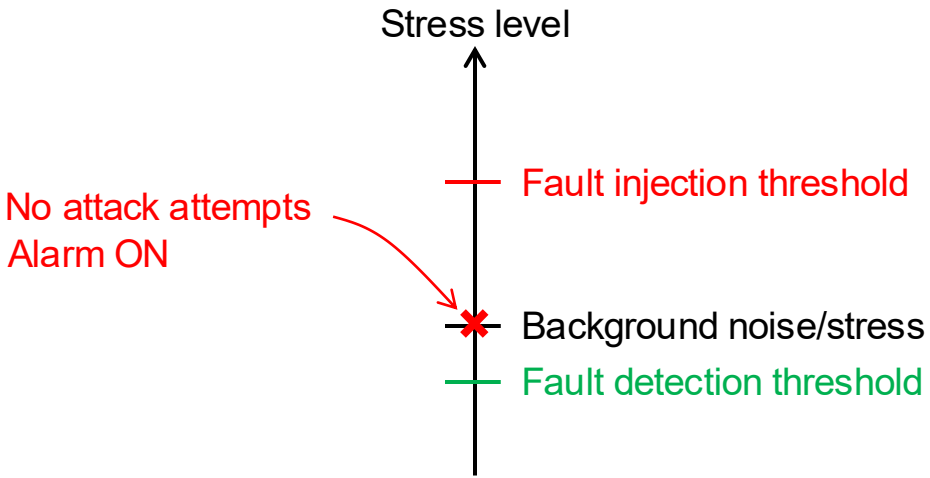


- However
  - ✓ Background noise/stress is not constant
  - ✓ The Fault detection threshold can be set low

→ They may cross leading to a False Positive sensor response

Sensor response classification

- False Positive case

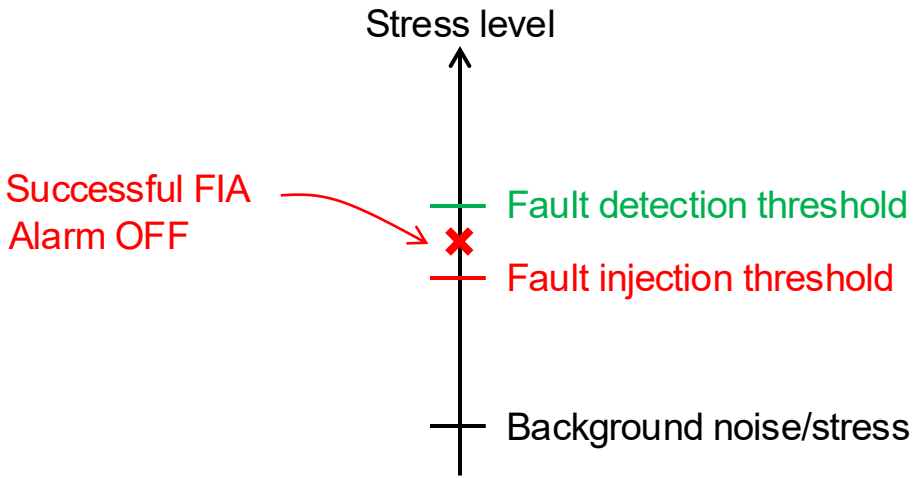


⇨ False Positive to be (absolutely) avoided → security policy is triggered

Key/data erasure, etc.
Similar to a denial of service

Sensor response classification

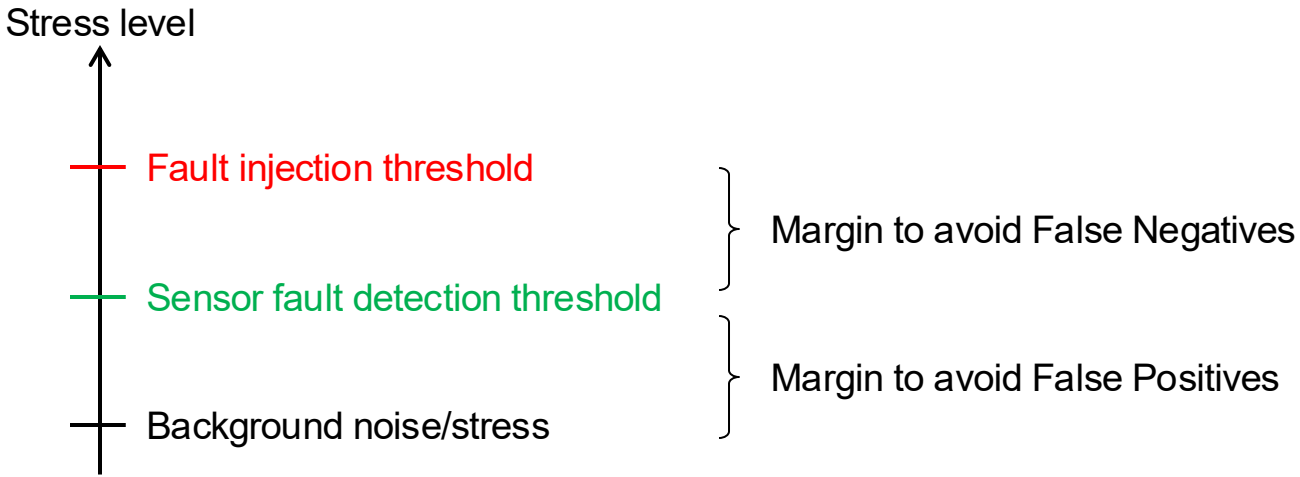
- False Negative case – Faull injection threshold < Fault detection threshold



- Injection/detection thresholds are not constant
  - ✓ Characteristics of the applied stress (duration, location, etc.)
  - ✓ Environmental conditions

Monitoring FIA with digital sensors – basics/principles

- Sensor detection threshold vs fault injection threshold



Monitoring FIA with Sensors – Lessons Learned

- Monitoring FIA with digital sensors – basics/principles

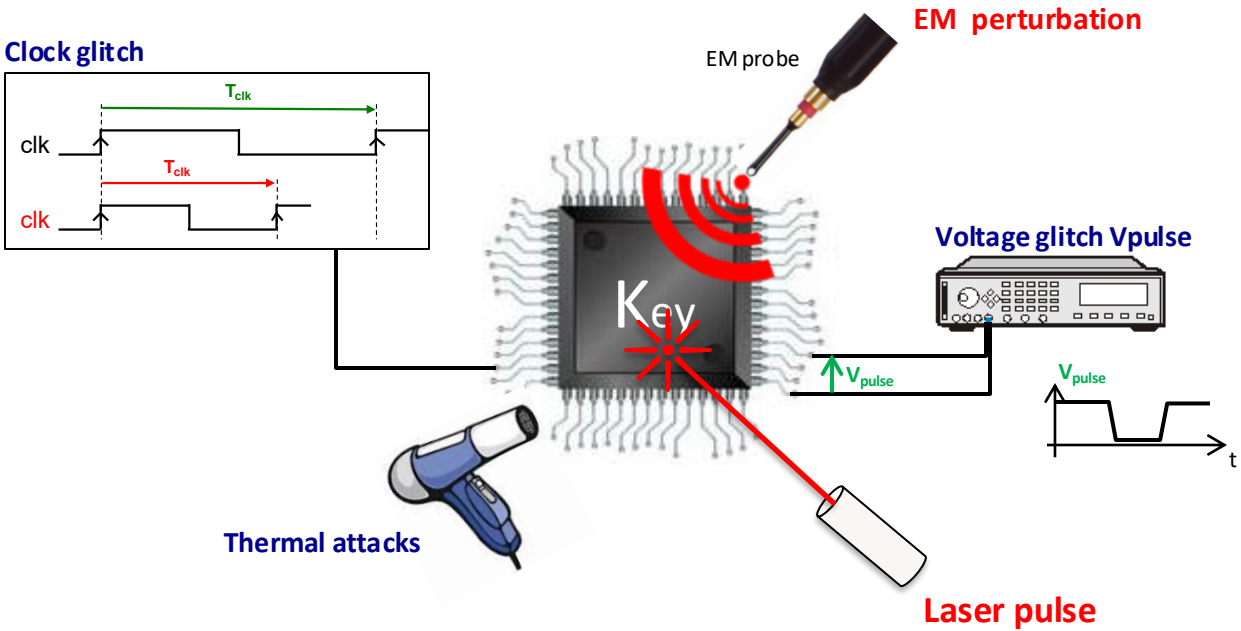
- Fault Injection Attacks

- EMFI detection sensors
- LFI detection sensors
- Conclusion

Fault Injection Attack basics

- Fault injection techniques

→ Disturbance of nominal operating conditions of a device target (ie stress attack)

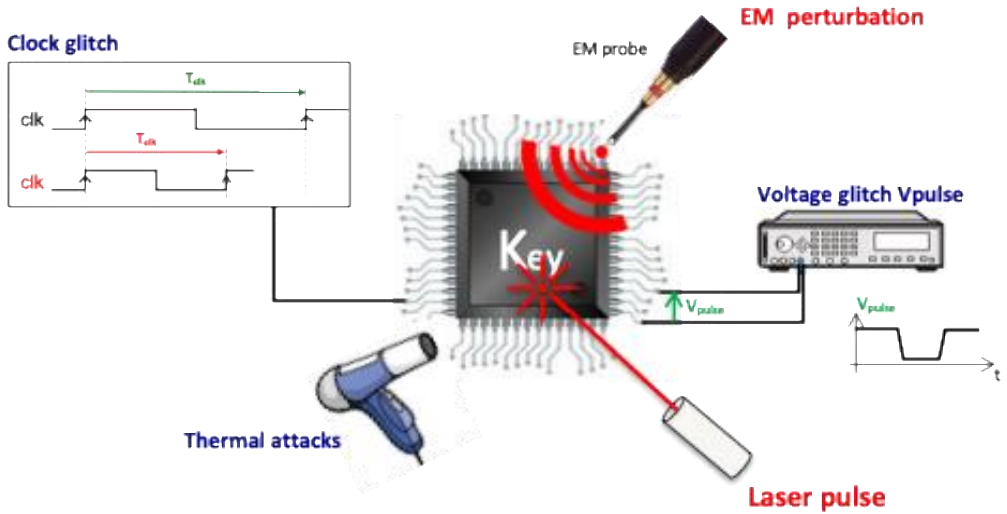


Fault Injection Attack basics

- Fault injection techniques

→ Disturbance of nominal operating conditions of a device target (ie stress attack)

  - Global effect, timing violation: clock, voltage supply, thermal perturbations
  - EMFI: local, timing violation
  - LFI: local
  - Radiation effects



Monitoring FIA with Sensors – Lessons Learned

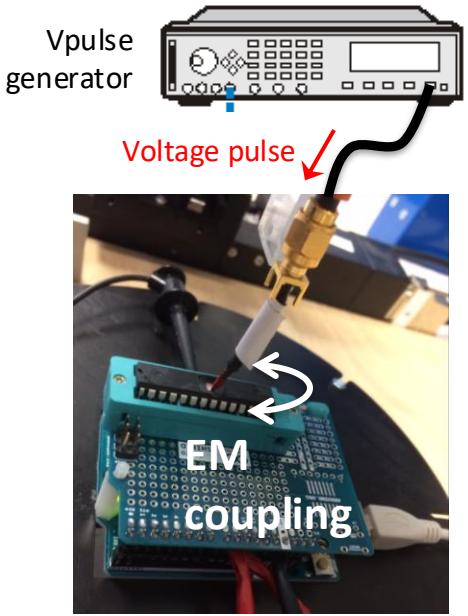
- Monitoring FIA with digital sensors – basics/principles
- Fault Injection Attacks

- EMFI detection sensors
  - EMFI mechanism
  - Delay-based sensor
  - DFF-based sensor
  - TDC-based sensor

- LFI detection sensors
- Conclusion

EMFI detection sensors

- EMFI mechanism



EM injection probe

EM pulse induced by Vpulse (rising and falling edges) through currents variations in the injection probe

⇩

EM coupling with the target's power/clock network

⇩

Induced transient in the target's power/clock network

⇩

Voltage and/or clock glitches

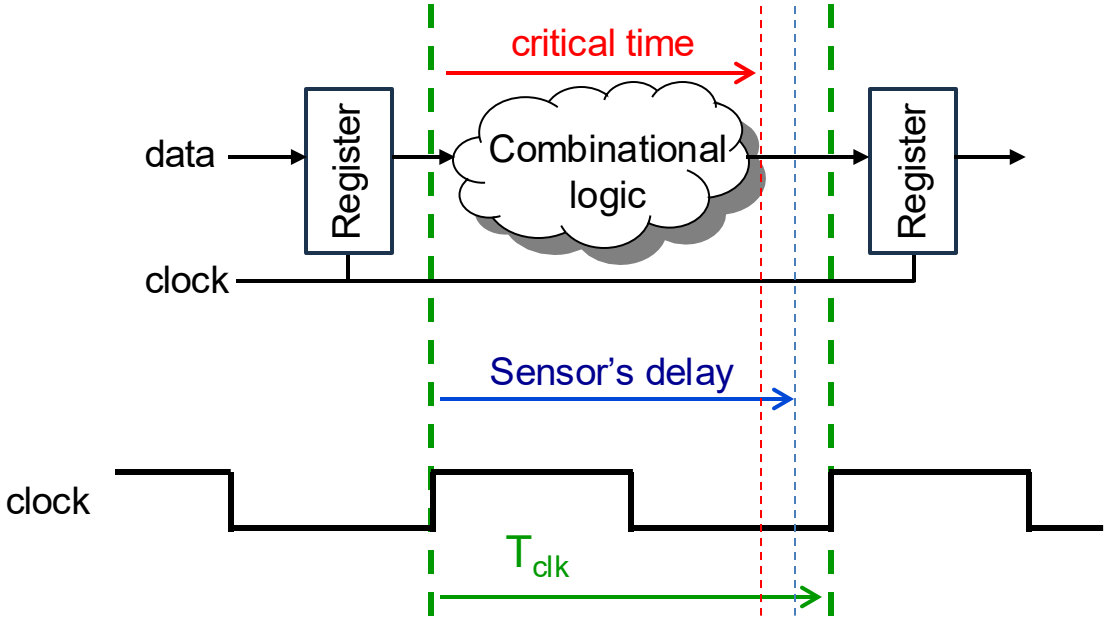
⇩

Timing constraints violation and faults!

R. Nabhan et al., Highlighting two EM fault models …, DATE 2023

EMFI detection sensors

- Delay-based sensor → Timing constraints monitoring of digital synchronous circuits
  - ✓ Idea: power supply and clock network stress can be monitored with a delay element

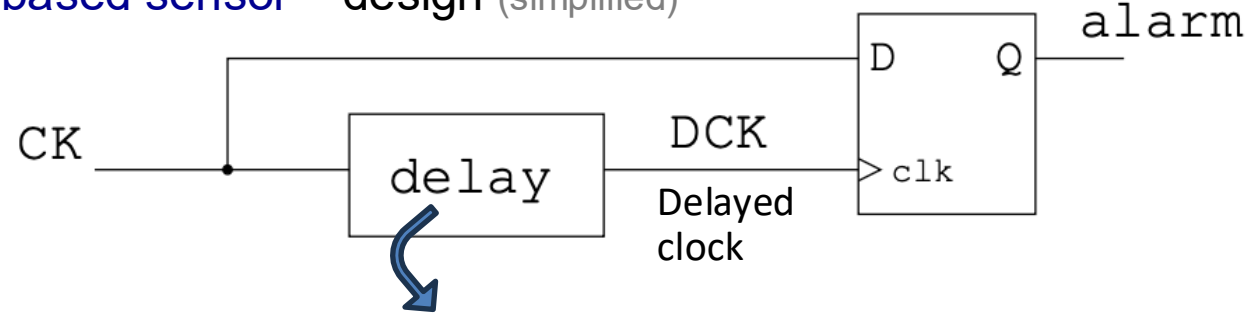


$Logic_{critical\ time} < T_{clk}$

$Logic_{critical\ time} < delay < T_{clk}$

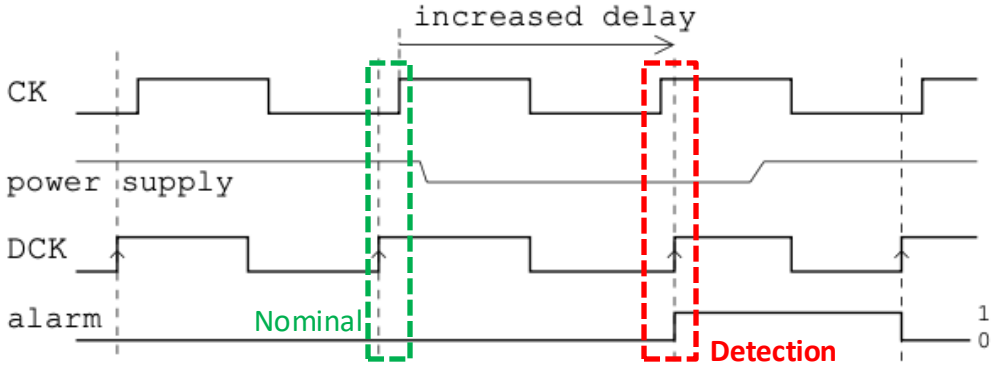
EMFI detection sensors

- Delay-based sensor – design (simplified)



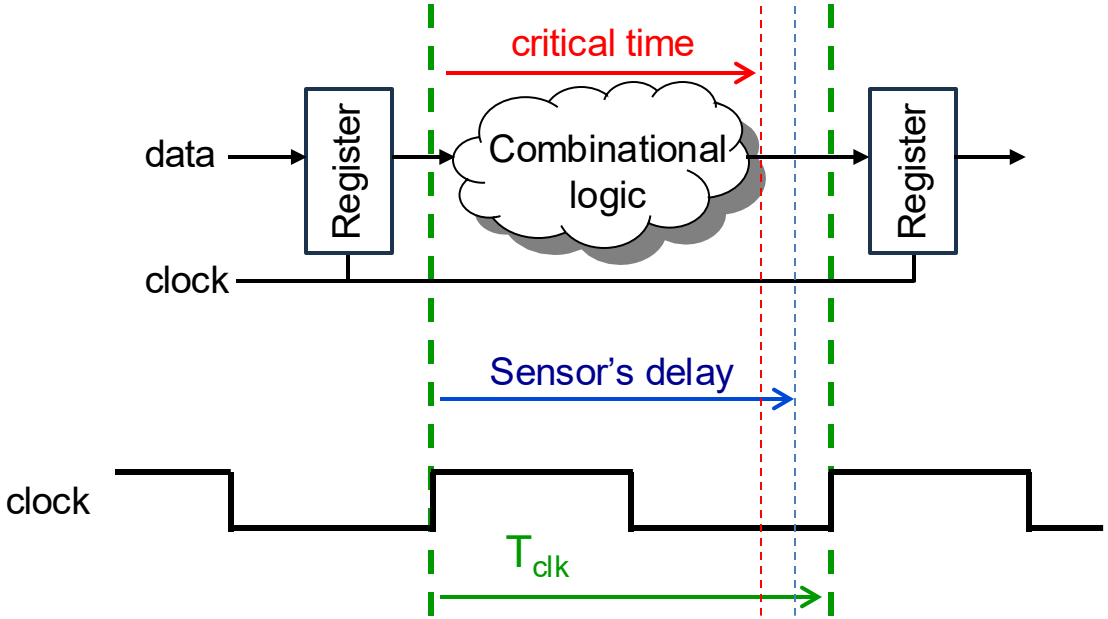
✓ Delay: increases with T° and voltage drop (also works for clock glitches)

→ Inversion of phase skew between CK and DCK → trigger the alarm



EMFI detection sensors

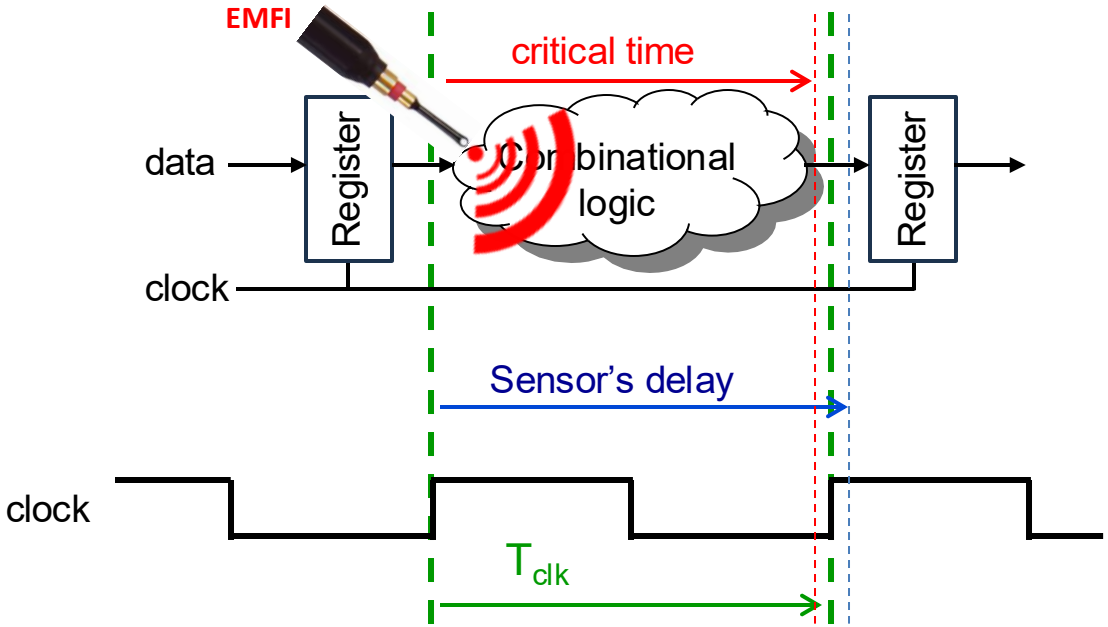
- Delay-based sensor → detection of an EMFI-induced voltage glitch



$Logic_{\ critical\ time} > delay > T_{clk}$

EMFI detection sensors

- Delay-based sensor → detection of an EMFI-induced voltage glitch
  → Similar for detection of an EMFI-induced clock glitch

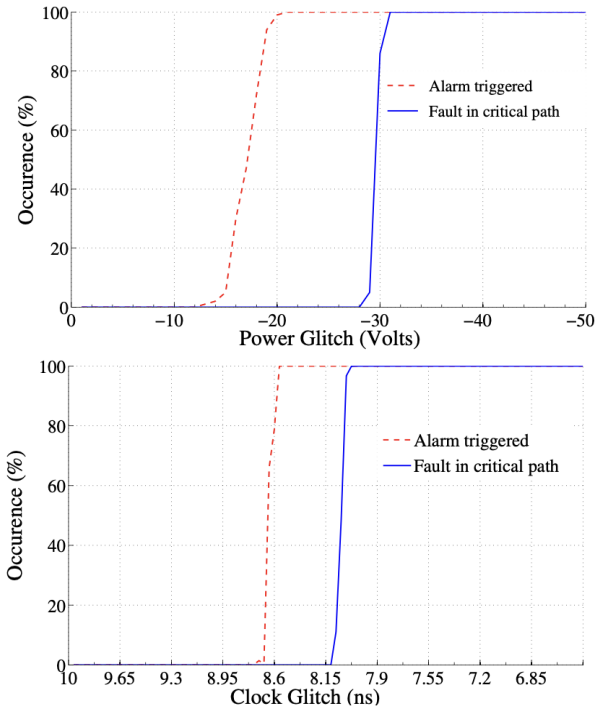


Logic $_{critical\ time}$ > T_{clk} > delay

→ Alarm triggered

EMFI detection sensors

- Delay-based sensor – Exp. validation
  - ✓ Test vehicle: Delay-based sensor + AES accelerator on FPGA



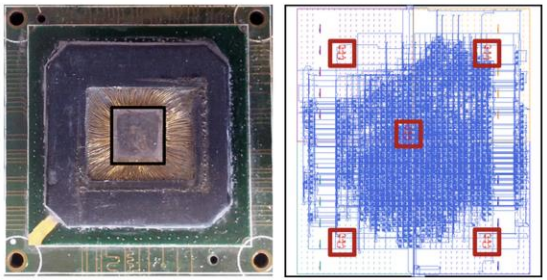
Voltage & clock glitches test series:
(applied externally)

- 100% detection rate
- No False Positive
- No Undetected fault

⇨ Fully efficient against global stress
Voltage, clock, temperature

EMFI detection sensors

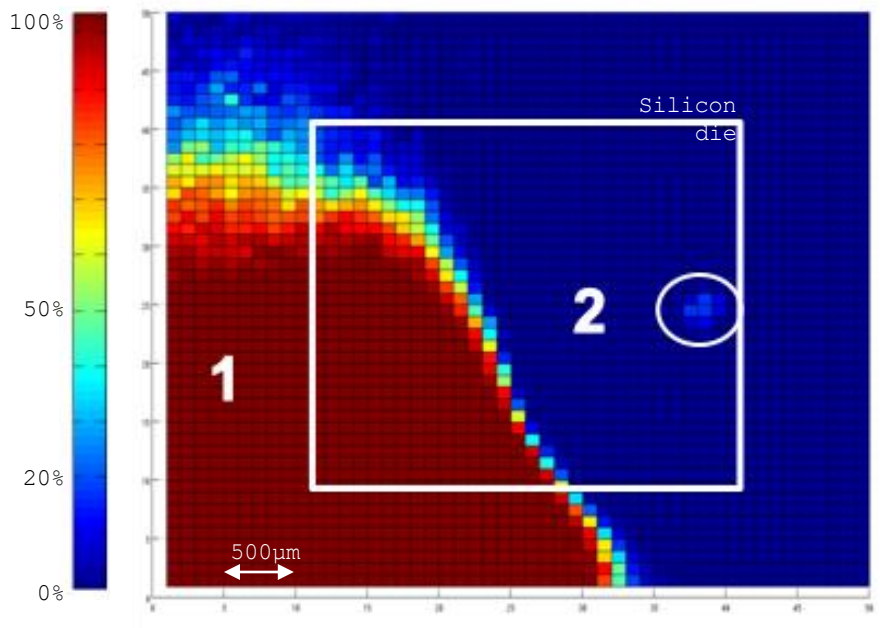
- Delay-based sensor – Exp. validation
  - ✓ EMFI test series → EMFI has a local effect



AES + 5 delay-based sensors

EMFI detection sensors

- Delay-based sensor – Exp. validation
  - ✓ EMFI test series → EMFI has a local effect



Single sensor test series

- Area 1 → Alarm triggered
- Area 2 → Fault injection

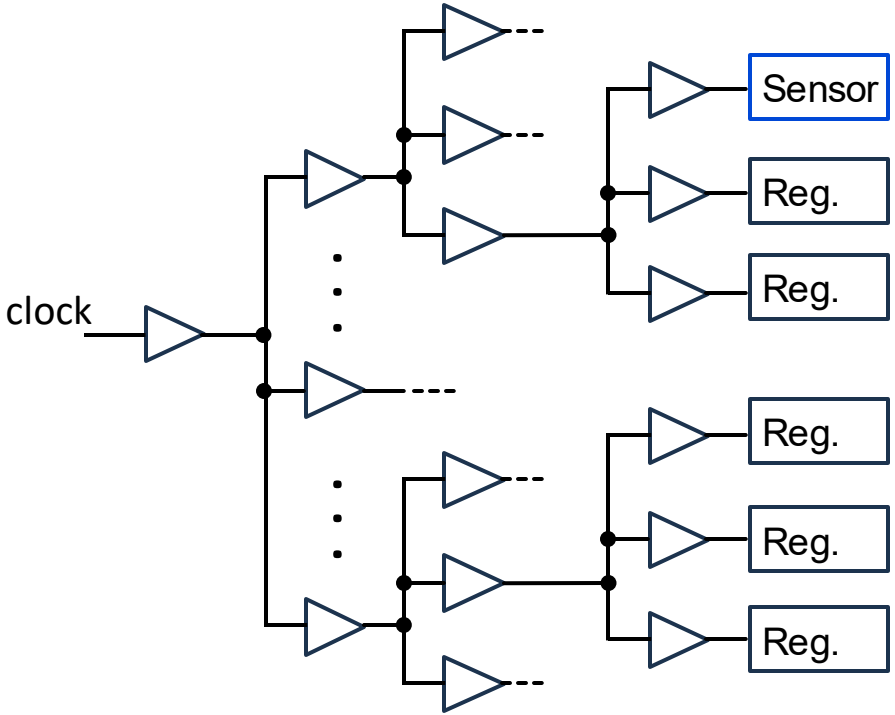
⇒ A delay-based sensor has a limited detection area

With 5-sensor configuration

Up to 10% of injected faults were undetected (depending of EMFI parameters)

EMFI detection sensors

- Delay-based sensor – Weakness analysis (assumption)
  - ✓ EMFI-induced clock glitch propagation in clock network/tree



EMFI detection sensors

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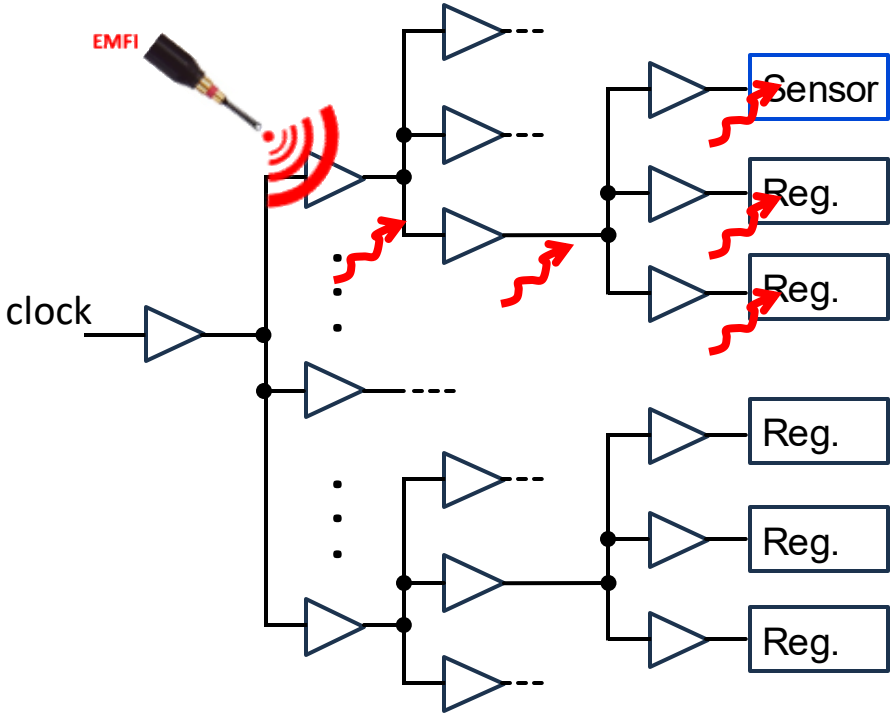

Clock path leading to a sensor
- Fault injection
- Fault Detection

EMFI detection sensors

- Delay-based sensor – Weakness analysis (assumption)
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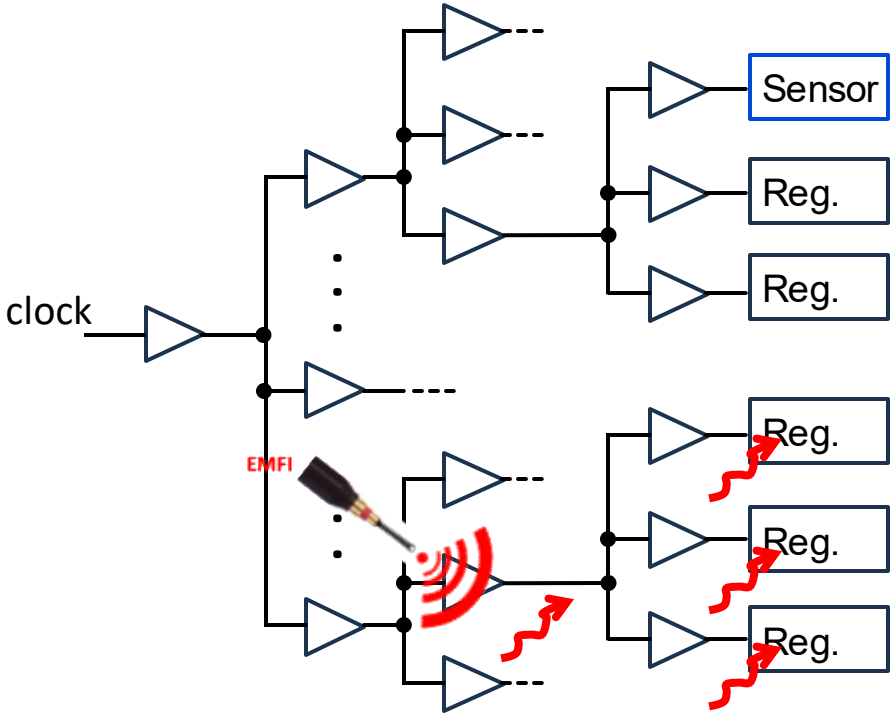
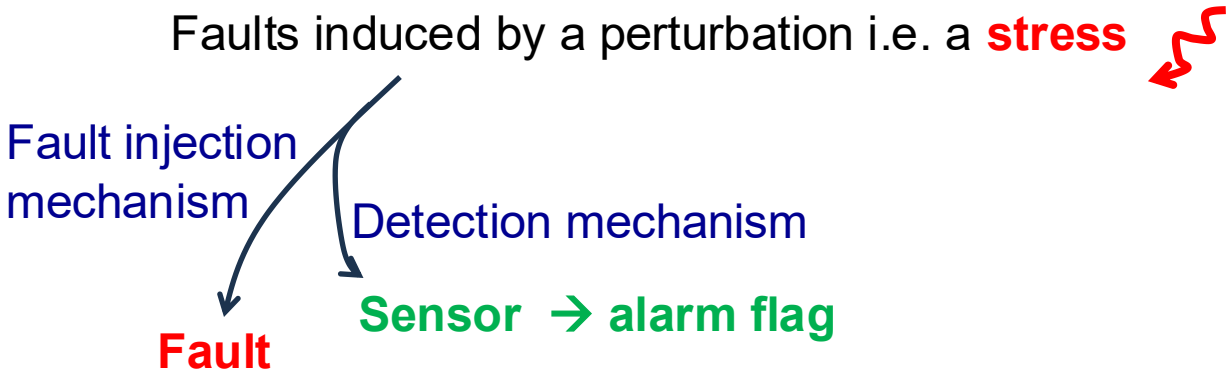


Clock path leading to a sensor
- Fault injection
- Fault Detection

Clock path with no sensor
- Fault injection
- Fault not detected

EMFI detection sensors

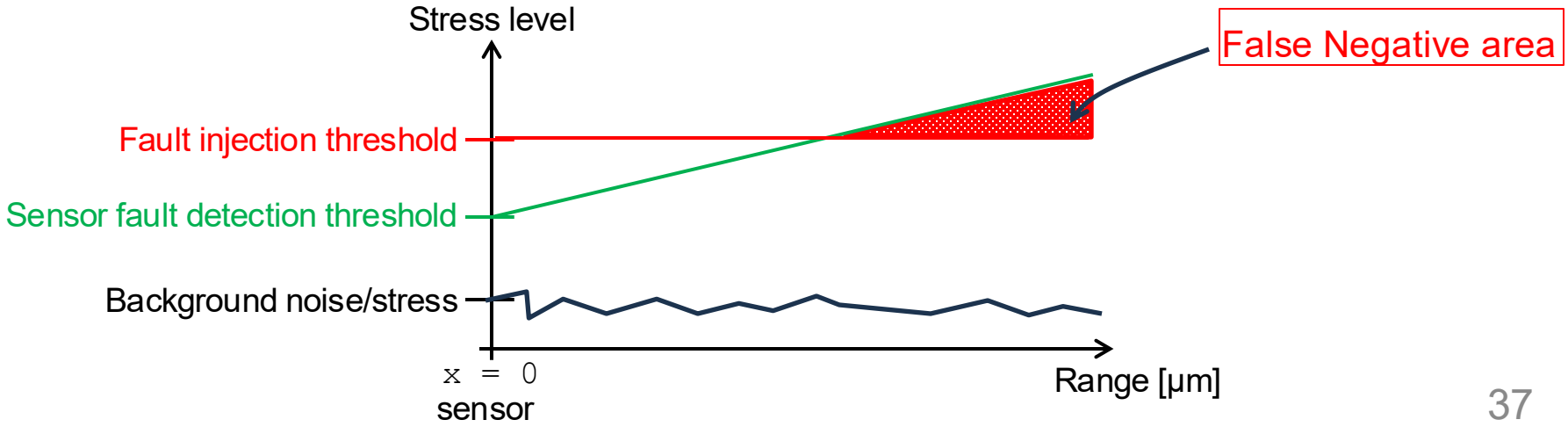
- Delay-based sensor
  - ✓ 100% effective to detect global T°, voltage and clock stresses



⇨ Optimal efficiency when detection & fault injection mechanisms match

EMFI detection sensors

- Delay-based sensor
  - ✓ 100% effective to detect global T°, voltage and clock stresses
  - ✓ Limited detection range against EMFI – local stress
  - ✓ Not designed to detect LFI
- Sensor detection range



Monitoring FIA with Sensors – Lessons Learned

- Monitoring FIA with digital sensors – basics/principles
- Fault Injection Attacks

- EMFI detection sensors
  - EMFI mechanism
  - Delay-based sensor
  - DFF-based sensor
  - TDC-based sensor

- LFI detection sensors
- Conclusion

EMFI detection sensors

- DFF-based sensor (El Baze et al. 2016)

→ EMFI Sampling fault model

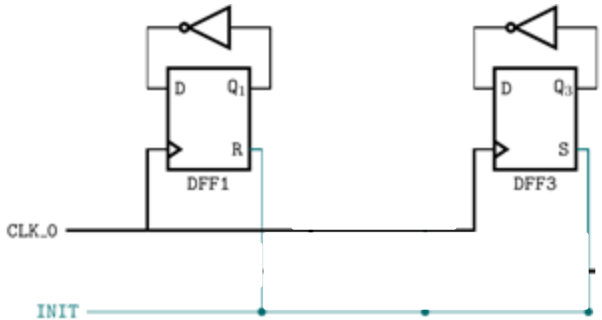
- ✓ Faults are induced at sampling time
- ✓ Recovery race between DFF input and clock signals

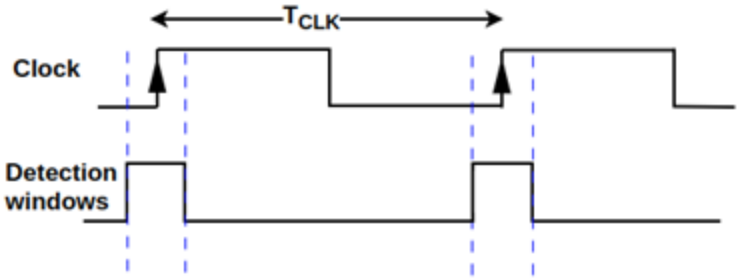
El Baze et al. A fully-digital EM pulse detector, DATE 2016
S. Ordas, et al., Electromagnetic fault injection: the curse of flip-flops, Journal of Cryptographic Engineering 2017

EMFI detection sensors

- DFF-based sensor – Design

→ Using toggling DFF to monitor and detect fault injection



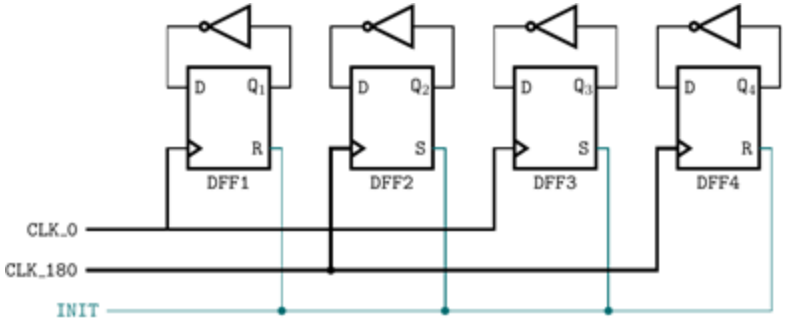


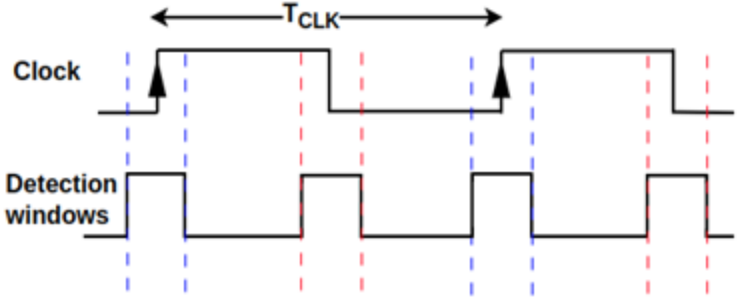
El Baze et al. A fully-digital EM pulse detector, DATE 2016

EMFI detection sensors

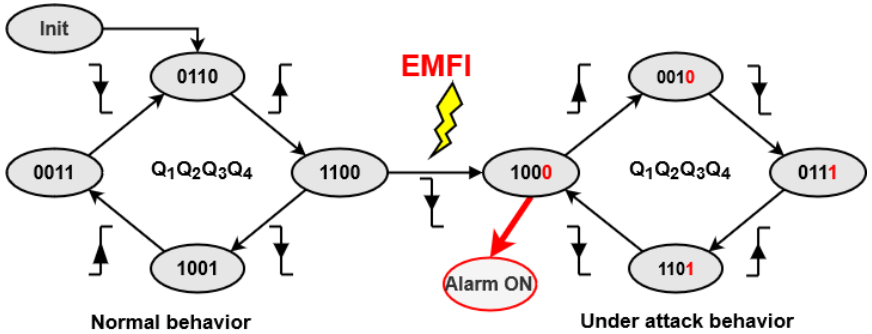
- DFF-based sensor – Design

→ Using toggling DFF to monitor and detect fault injection





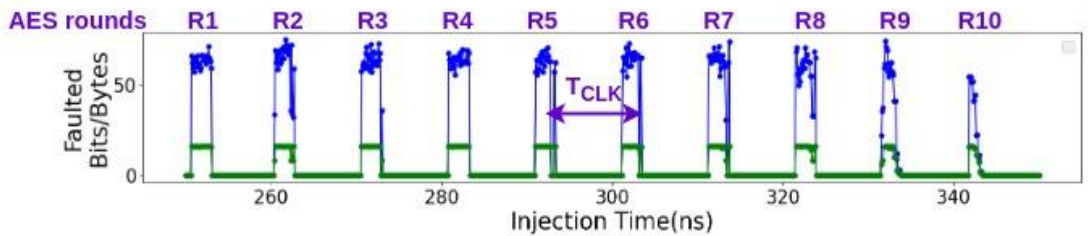
- Faulting a DFF modifies the toggling pattern → EMFI detection



El Baze et al. A fully-digital EM pulse detector, DATE 2016

EMFI detection sensors

- DFF-based sensor – Exp validation
  - ✓ EMFI test series on FPGA: AES (max. freq. 200 MHz) + sensors
  - ✓ At 100 MHz, 420V (Vpulse amplitude given as a measure of applied stress)



Timing of AES faults
T_{CLK} periodic

EMFI detection sensors

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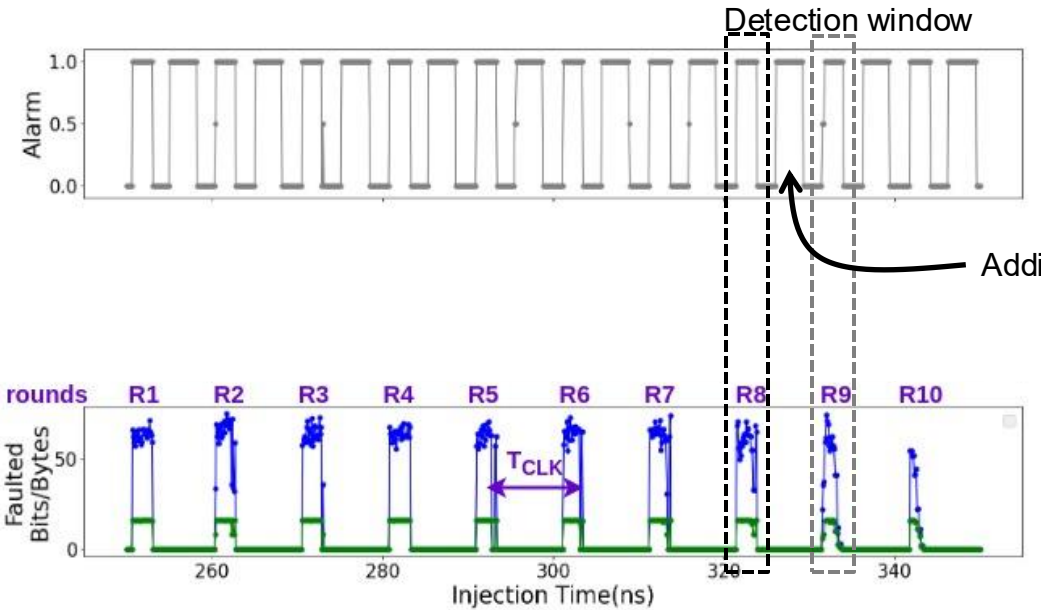

Detection of EMFI
Periodic detection windows

Timing of AES faults
T_{CLK} periodic

EMFI detection sensors

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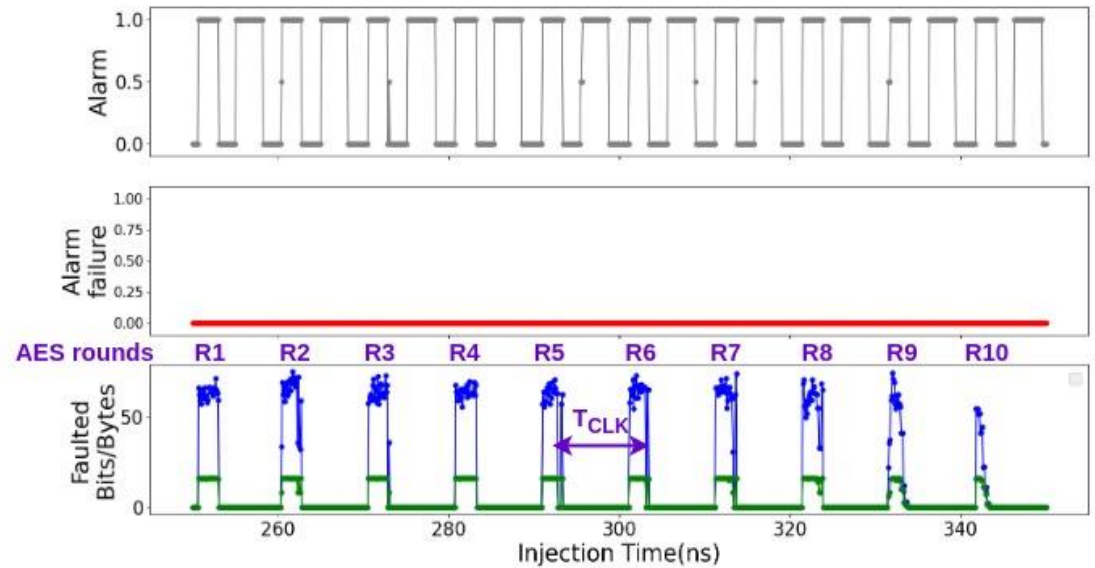


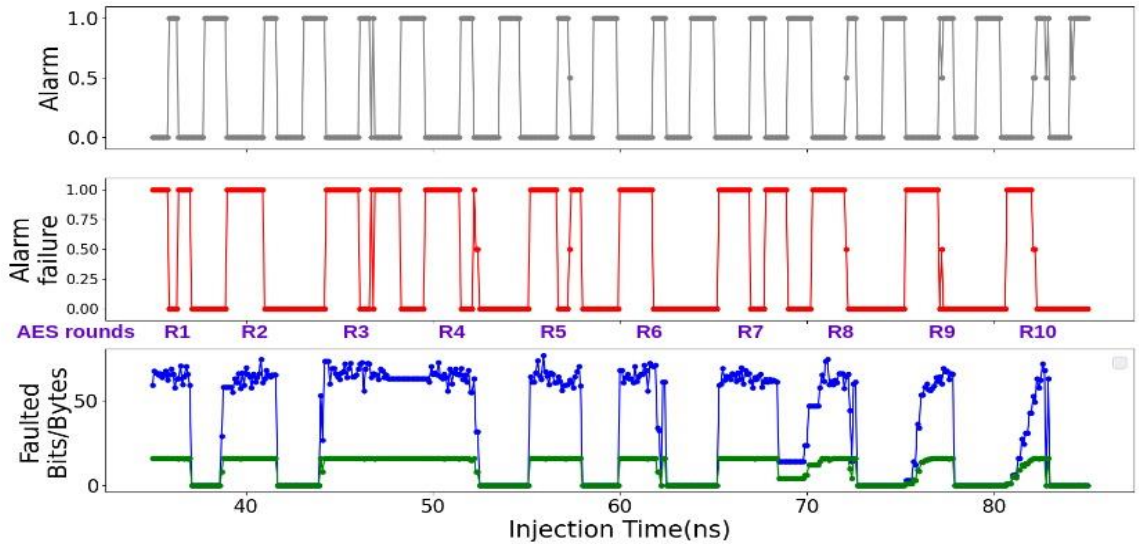
Detection of EMFI
Periodic detection windows

No alarm failure

Timing of AES faults
T_{CLK} periodic

EMFI detection sensors

- DFF-based sensor – Exp validation
  - ✓ EMFI test series on FPGA: AES (max. freq. 200 MHz) + sensors
  - ✓ At **200 MHz**, 420V (Vpulse amplitude given as a measure of applied stress)



Detection of EMFI

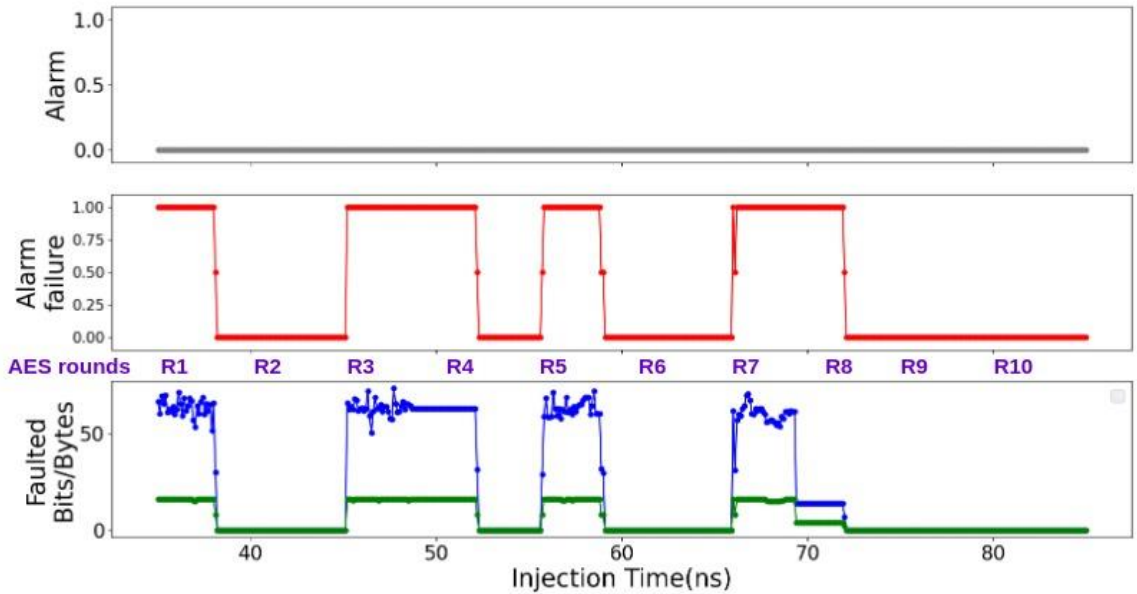
⇨ Undetected FIA

Timing of AES faults

Enlarged fault windows

EMFI detection sensors

- DFF-based sensor – Exp validation
  - ✓ EMFI test series on FPGA: AES (max. freq. 200 MHz) + sensors
  - ✓ At **200 MHz**, **350V** (Vpulse amplitude given as a measure of applied stress)



No detection of EMFI

Undetected FIA

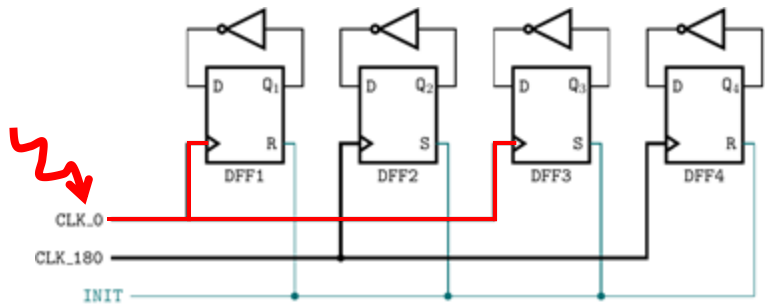
Timing of AES faults

EMFI detection sensors

- DFF-based sensor – Analysis
  - ✓ EMFI at 420V → clock + voltage glitches
  - ✓ EMFI at 350V → voltage glitch only

EMFI detection sensors

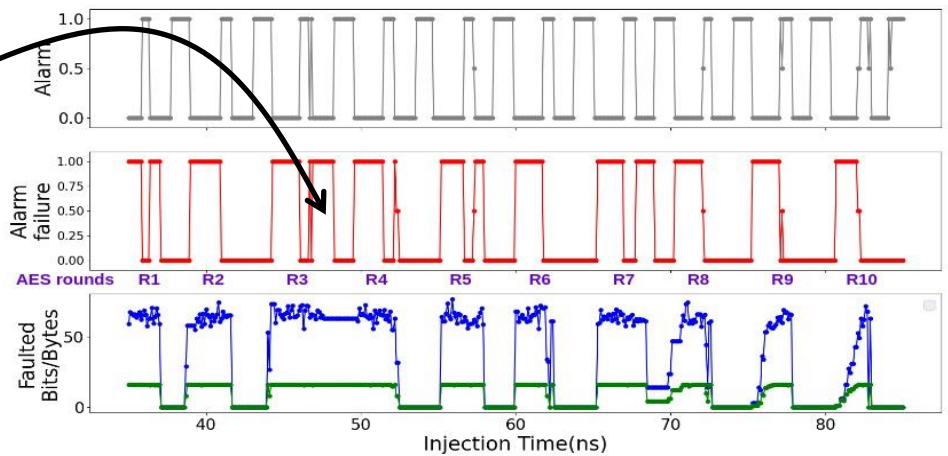
- DFF-based sensor – Analysis
  - ✓ EMFI at 420V → clock + voltage glitches
  - ✓ EMFI at 350V → voltage glitch only
  - ✓ At 100 MHz, 420V → clock glitch induced faults → successful detection
    Modification of DFFs toggling pattern



EMFI detection sensors

- DFF-based sensor – Analysis
  - ✓ EMFI at 420V → clock + voltage glitches
  - ✓ EMFI at 350V → voltage glitch only
  - ✓ At **200 MHz**, 420V → clock + voltage glitches induced faults → partial EMFI detection
    Low slack

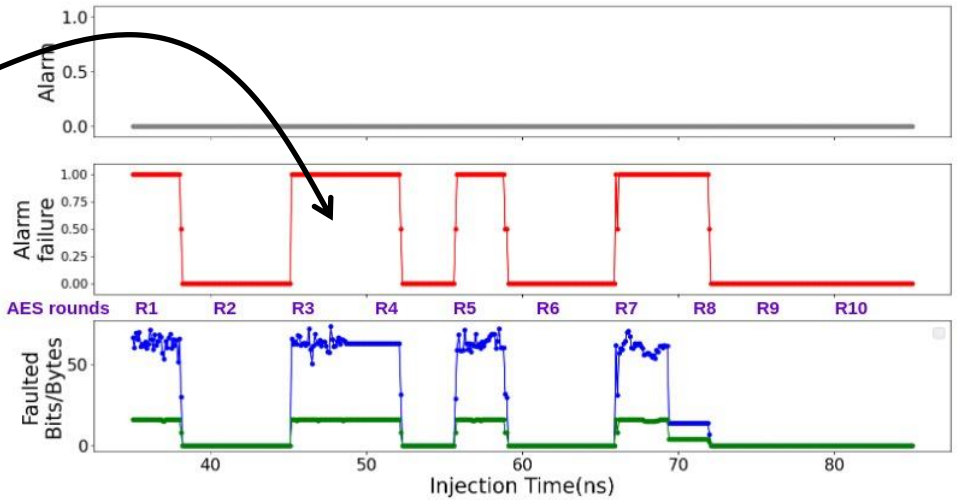
Delay fault
Undetected timing violation



EMFI detection sensors

- DFF-based sensor – Analysis
  - ✓ EMFI at 420V → clock + voltage glitches
  - ✓ EMFI at 350V → voltage glitch only
  - ✓ At **200 MHz**, **350V** → voltage glitches induced faults → No EMFI detection
    Low slack

Delay fault
Undetected timing violation



EMFI detection sensors

- DFF-based sensor – Analysis
  - ✓ High risk of undetected faults when fault and detection mechanisms are different

Monitoring FIA with Sensors – Lessons Learned

- Monitoring FIA with digital sensors – basics/principles
- Fault Injection Attacks

- EMFI detection sensors
  - EMFI mechanism
  - Delay-based sensor
  - DFF-based sensor
  - TDC-based sensor

- LFI detection sensors
- Conclusion

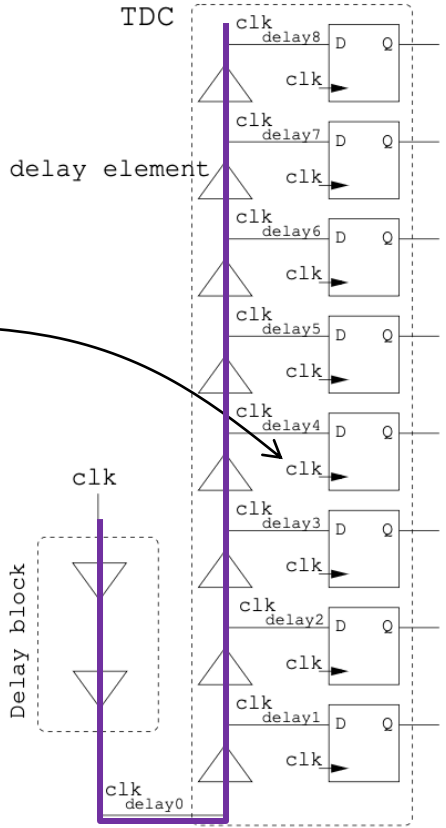
EMFI detection sensors

- TDC-based sensor – theory
  - ✓ Delay-based

→ Output: a digital image of the delay

Main clock

- ✓ Sampling clock of DFFs
- ✓ Delayed and sampled



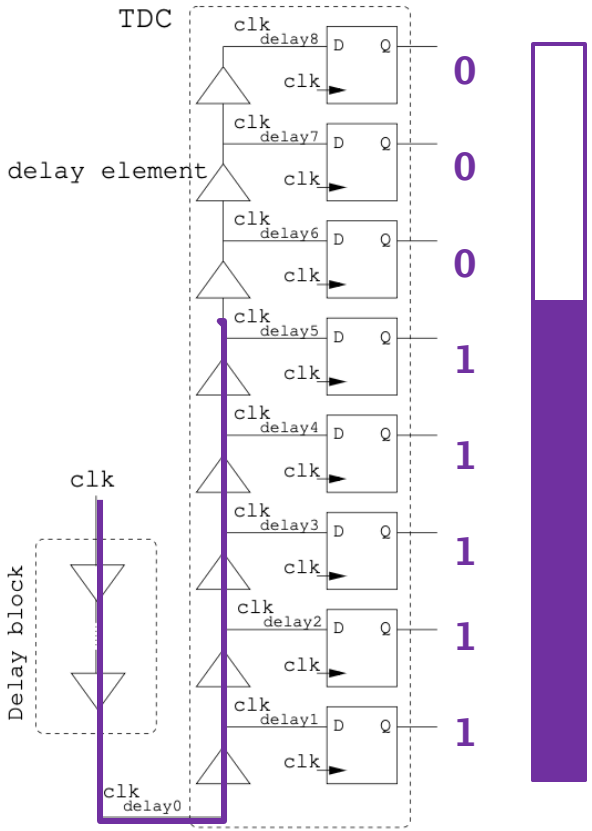
TDC = Time to Digital Converter

EMFI detection sensors

- TDC-based sensor – theory
  - ✓ Delay-based

→ Output: a digital image of the delay

  - ✓ Thermometer code



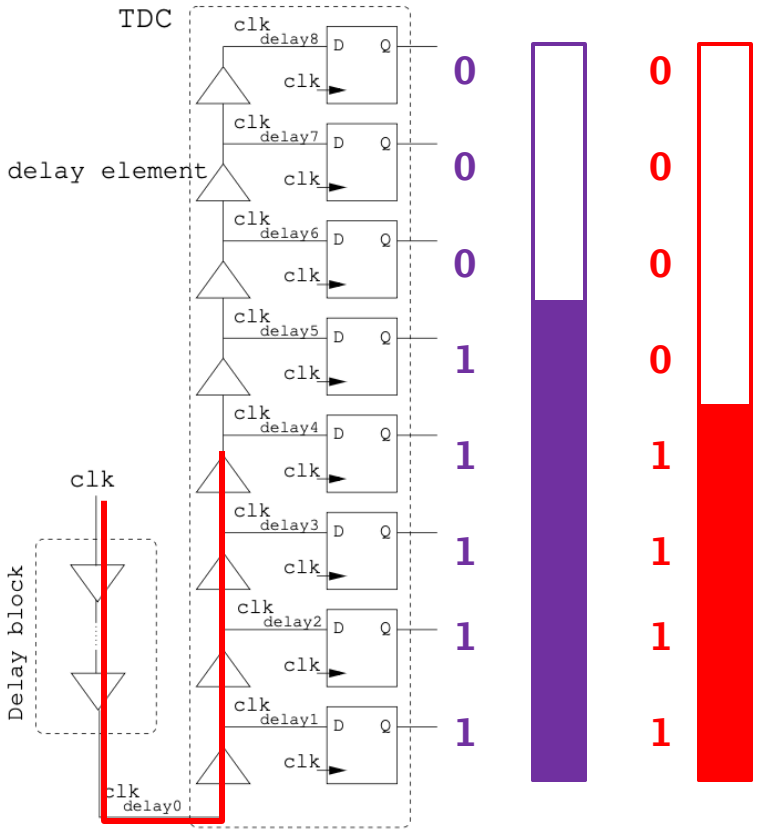
EMFI detection sensors

- TDC-based sensor – theory
  - ✓ Delay-based

→ Output: a digital image of the delay

  - ✓ Thermometer code

- EMFI-induced voltage glitch
  - ✓ Increased delay



EMFI detection sensors

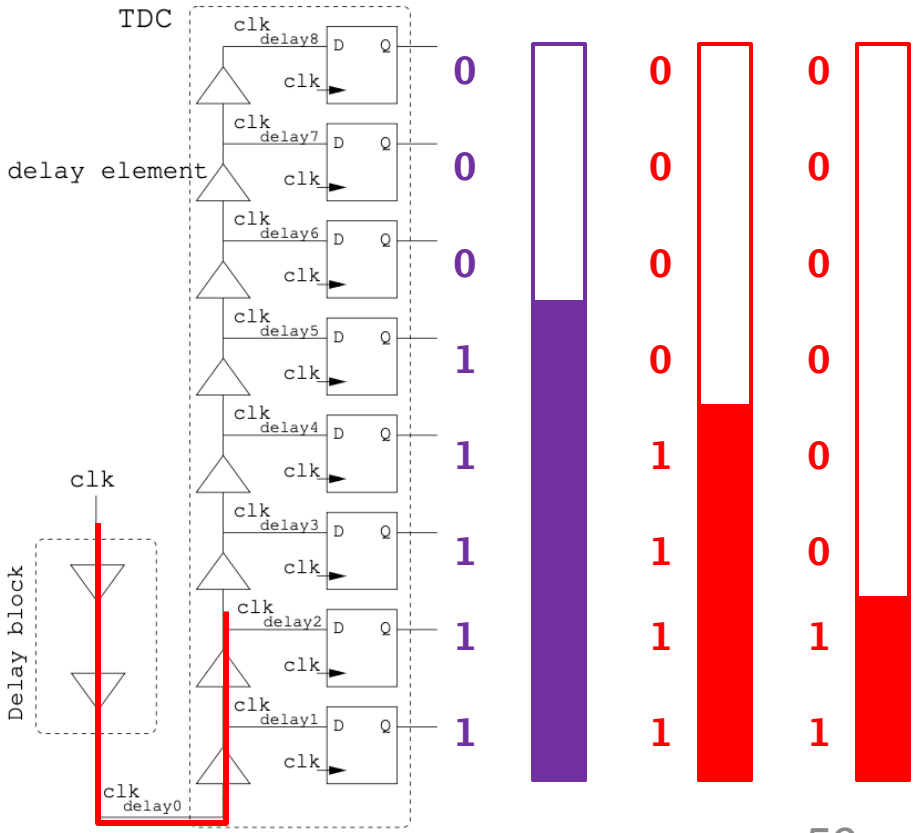
- TDC-based sensor – theory
  - ✓ Delay-based

→ Output: a digital image of the delay

  - ✓ Thermometer code

- EMFI-induced voltage glitch
  - ✓ Increased delay
- EMFI-induced clock glitch
  - ✓ Early sampling

⇨ EMFI detection through TDC output monitoring



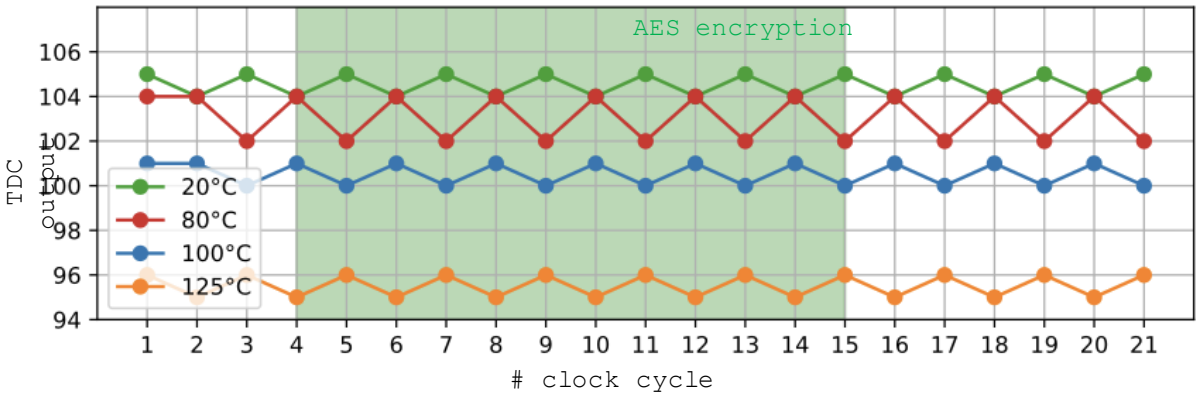
EMFI detection sensors

- TDC-based sensor – Tested design
  - ✓ FPGA: AES + 3 TDC sensors

- Test of operating conditions
  - ✓ T° and voltage supply both affect the measured propagation delays
  - → Relevant alarm triggering strategy?

EMFI detection sensors

- TDC-based sensor – Effect of temperature variations
  - ✓ TDC output on the -40°C – 140°C temperature range



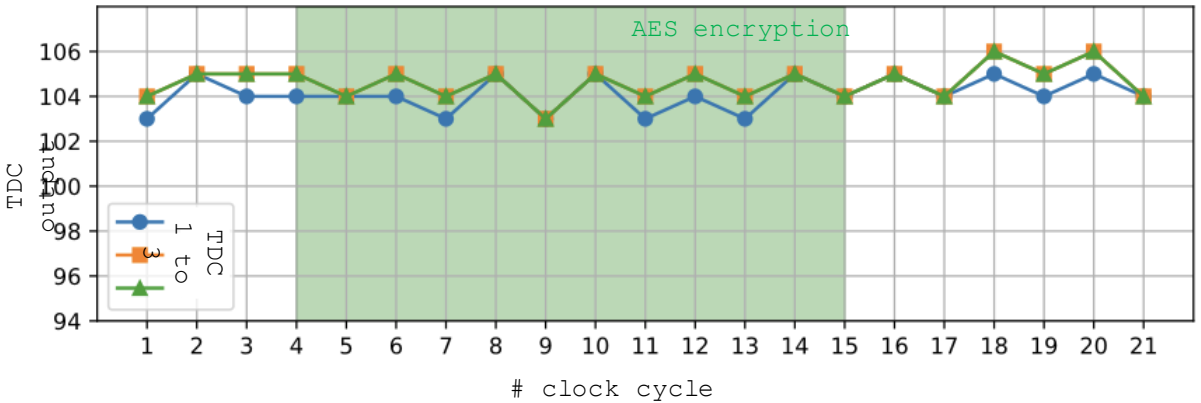
Thermal chamber

- TDC output
  - ✓ 104-106 at 20°C
  - ✓ 95-96 at 125°C

R. Nabhan, et al., HEED: A Highly Efficient Electromagnetic Fault Detection Scheme, DATE 2026

EMFI detection sensors

- TDC-based sensor – Effect of power supply noise
  - ✓ Dynamic noise generated by switching ON/OFF dedicated noise IPs

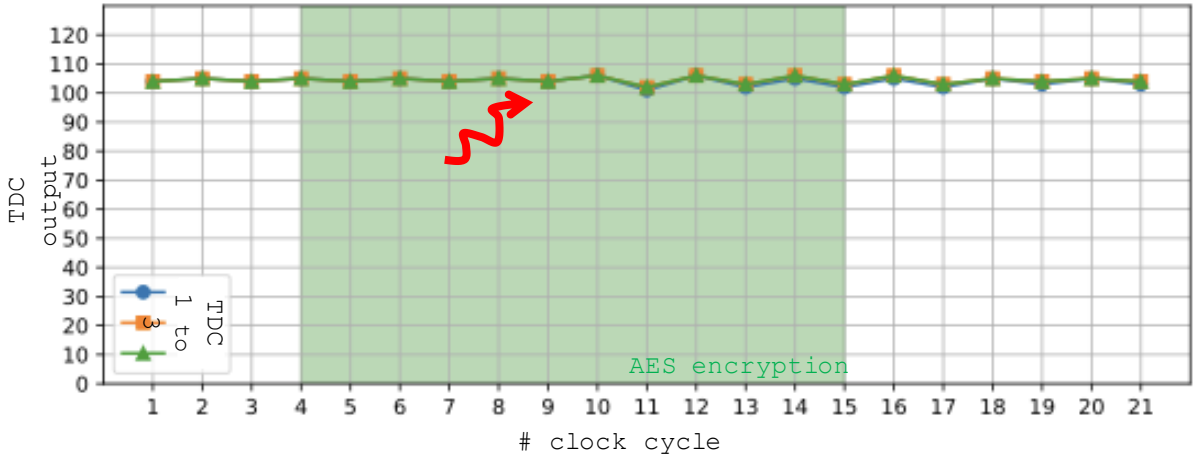


- TDC output variations (at room temperature)
  - ✓ $|\text{TDC Output}_n - \text{TDC Output}_{n-1}| \leq 2$

R. Nabhan, et al., HEED: A Highly Efficient Electromagnetic Fault Detection Scheme, DATE 2026

EMFI detection sensors

- TDC-based sensor – EMFI experiments
  - ✓ For EMFI parameters resulting in successful fault injection into the AES computations

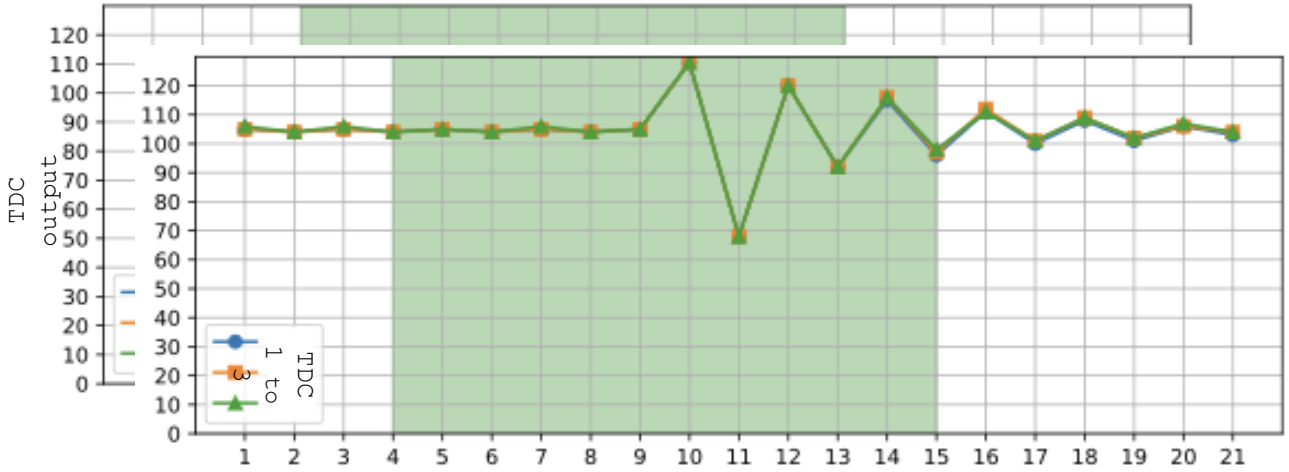


EMFI at the fault threshold

- TDC output variations leading to fault injection
  - ✓ $|\text{TDC Output}_n - \text{TDC Output}_{n-1}| \geq 3$

EMFI detection sensors

- TDC-based sensor – EMFI experiments
  - ✓ For EMFI parameters resulting in successful fault injection into the AES computations

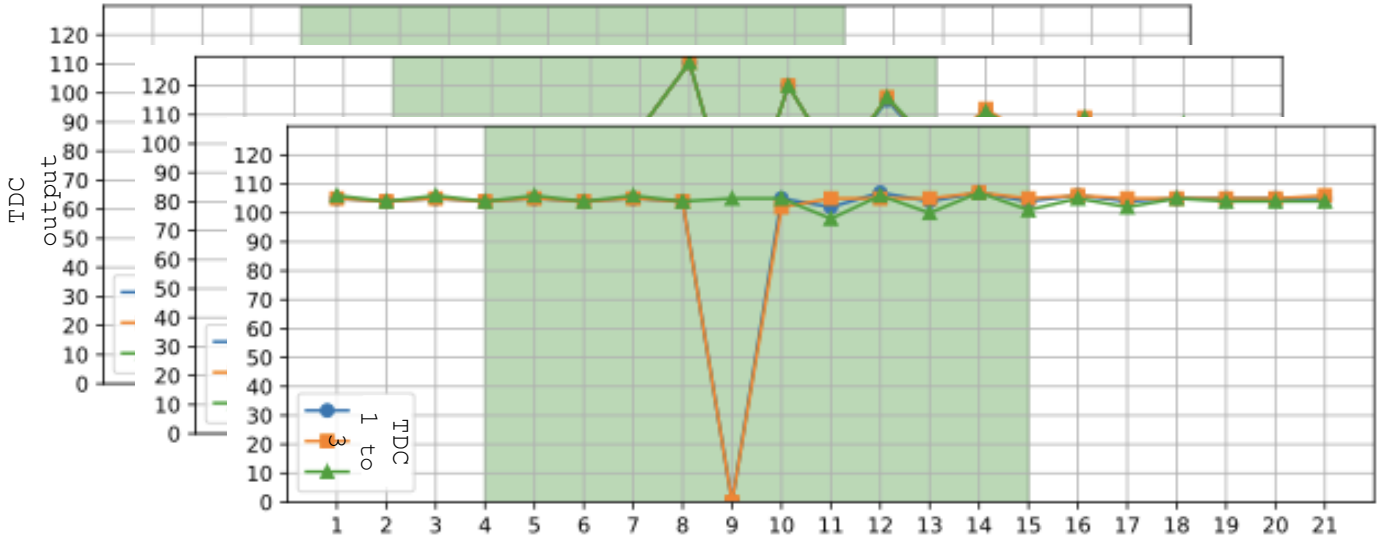


Strong EMFI

- TDC output variations leading to fault injection
  - ✓ $|\text{TDC Output}_n - \text{TDC Output}_{n-1}| \geq 3$

EMFI detection sensors

- TDC-based sensor – EMFI experiments
  - ✓ For EMFI parameters resulting in successful fault injection into the AES computations

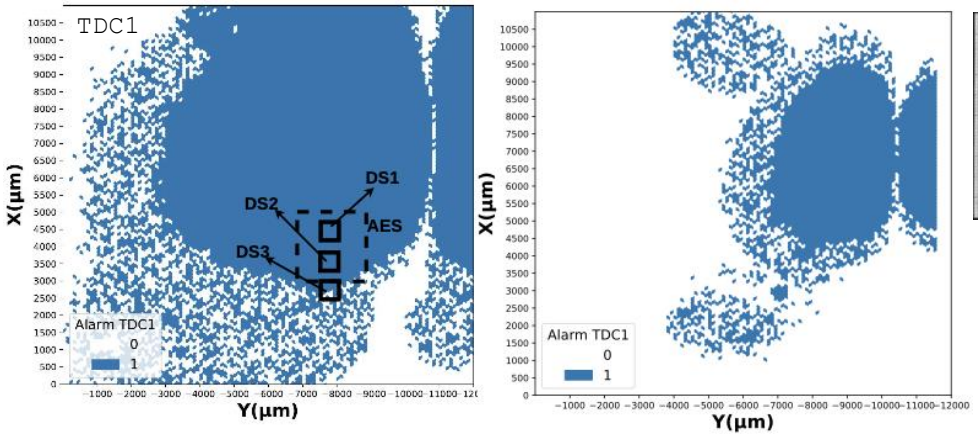


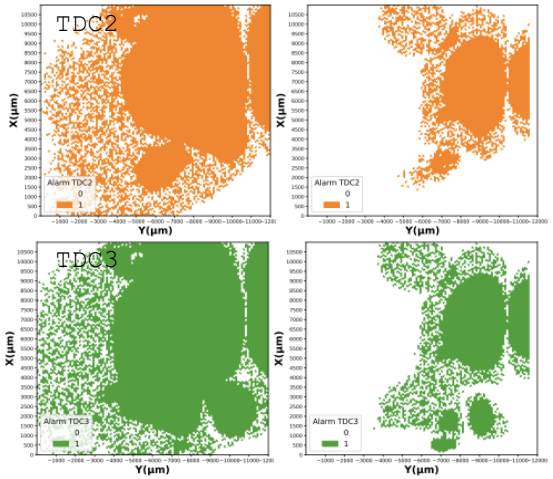
EMFI induced clock glitch

- TDC output variations leading to fault injection
  - ✓ $|\text{TDC Output}_n - \text{TDC Output}_{n-1}| \geq 3$

EMFI detection sensors

- TDC-based sensor – Detection strategy
  - ✓ Alarm triggered for $|\text{TDC Output}_n - \text{TDC Output}_{n-1}| > 2$
  - → 100% fault detection rate
  - → 1% False Positive (unwanted alarms due to noise ; 17 FP out of 1,650 tests)
- Large detection area – drawn for various EMFI parameters

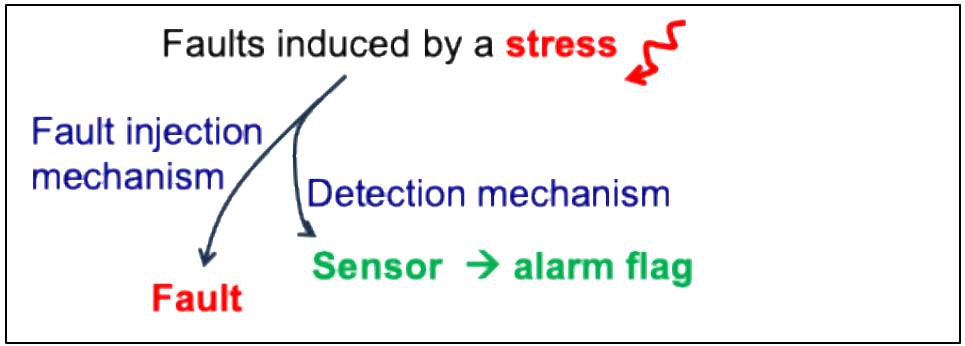




EMFI detection sensors

- Conclusion

  - ✓ EMFI detection = still an open subject
  - ✓ Exp. testing is mandatory (including at various nominal and stress conditions)
  - ✓ Choose a detection mechanism matching the fault injection mechanism



Monitoring FIA with Sensors – Lessons Learned

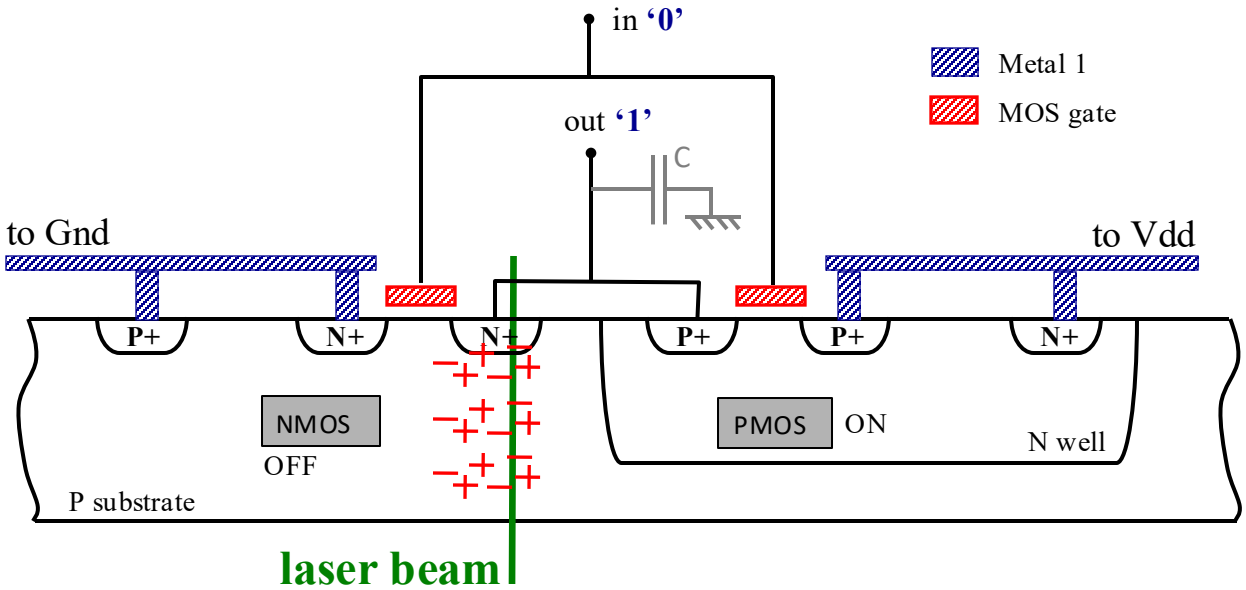
- Monitoring FIA with digital sensors – basics/principles
- Fault Injection Attacks
- EMFI detection sensors

- LFI detection sensors
  - LFI mechanism
  - TDC-based sensor
  - BBICS Bulk Built-In Current Sensor

- Conclusion

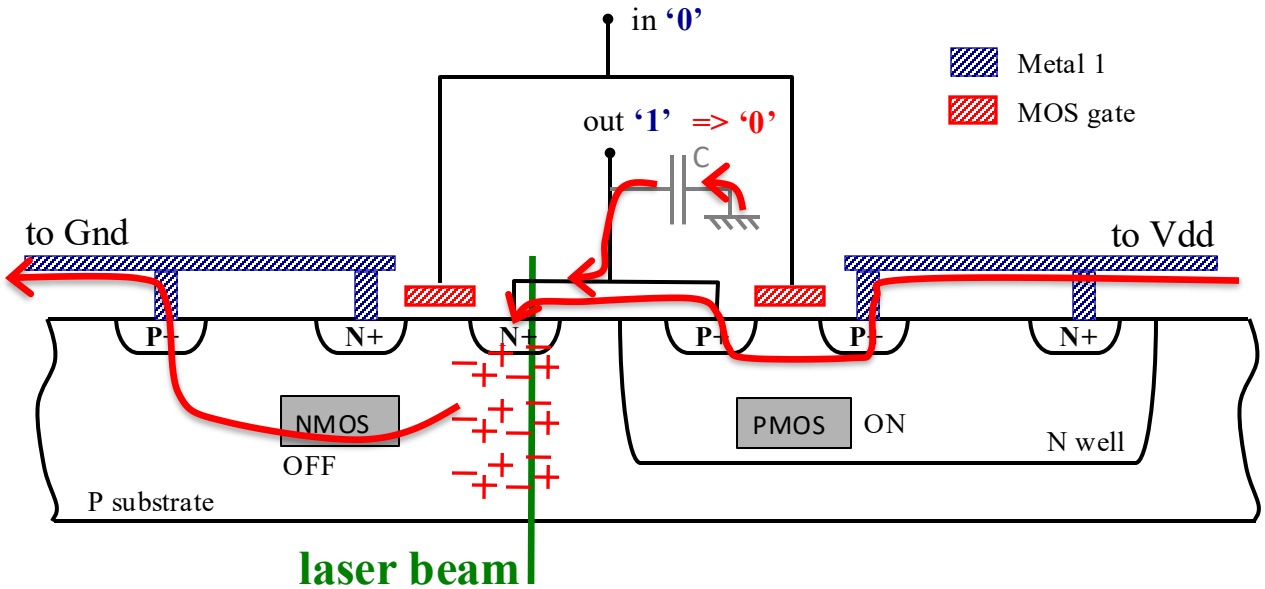
LFI detection sensors

- LFI mechanism – Laser induced photocurrent $(\lambda \leq 1{,}100\, nm)$
  - ✓ Inverter cross section



LFI detection sensors

- LFI mechanism – Laser-induced photocurrent ($\lambda \leq 1{,}100\,nm$)
  - ✓ Inverter cross section



⇨ Laser-induced I_{ph} ⇨ Logical faults

Monitoring FIA with Sensors – Lessons Learned

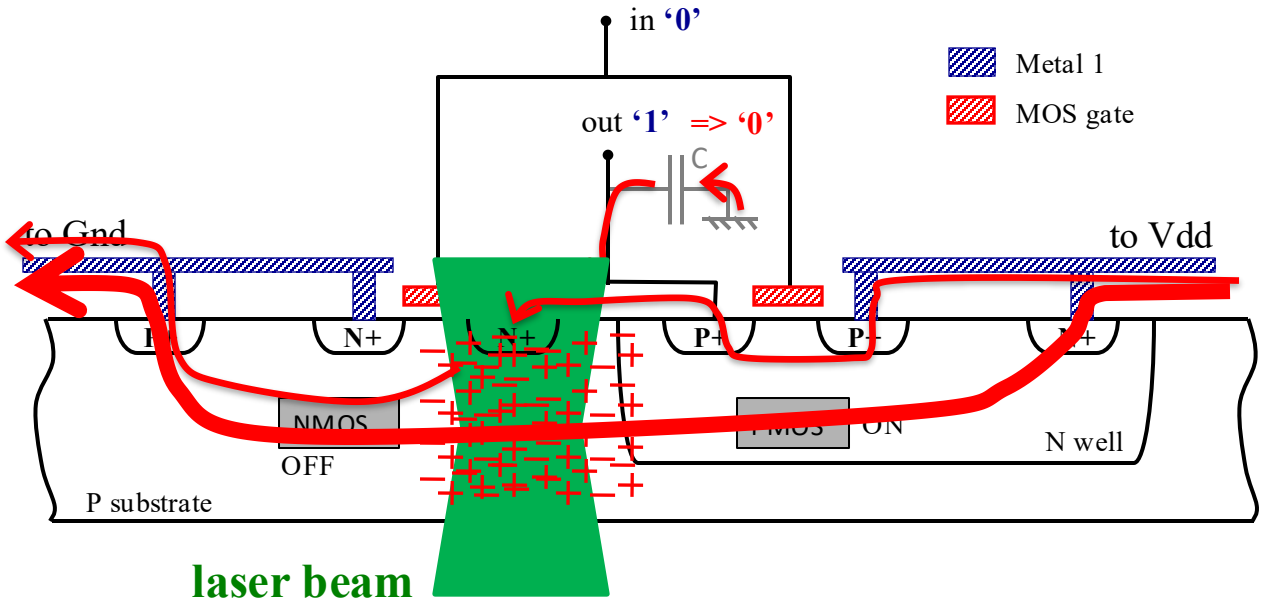
- Monitoring FIA with digital sensors – basics/principles
- Fault Injection Attacks
- EMFI detection sensors

- LFI detection sensors
  - LFI mechanism
  - TDC-based sensor
  - BBICS Bulk Built-In Current Sensor

- Conclusion

LFI detection sensors

- TDC-based sensor – Principle



Laser-induced Vdd to Gnd current (large)

⇩

IR-drop

⇩

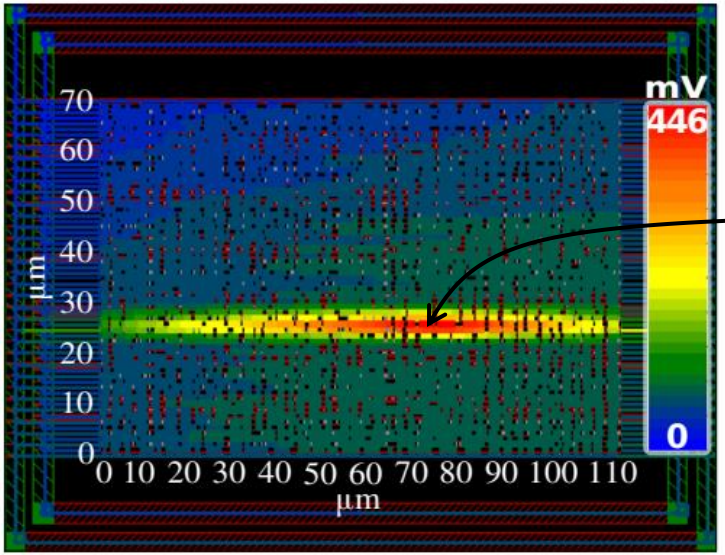
Increase of logic propagation times

⇩

Detection by TDC-based sensor

LFI detection sensors

- TDC-based sensor – Principle
  - ✓ Laser-induced IR-drop (simulation, 5 µm laser spot)
  - → Propagation of a significant IR-drop at a large distance

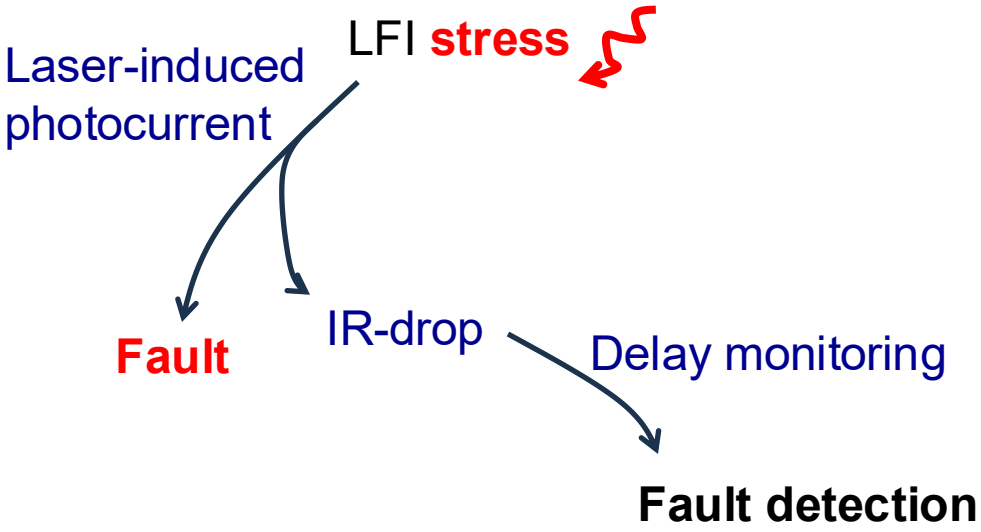


ARM7 CPU, CMOS 28nm, 5k+ gates

R. Viera et al., Simulation and experimental demonstration of the importance of IR-drops during laser fault-injection, IEEE TCAD 2019

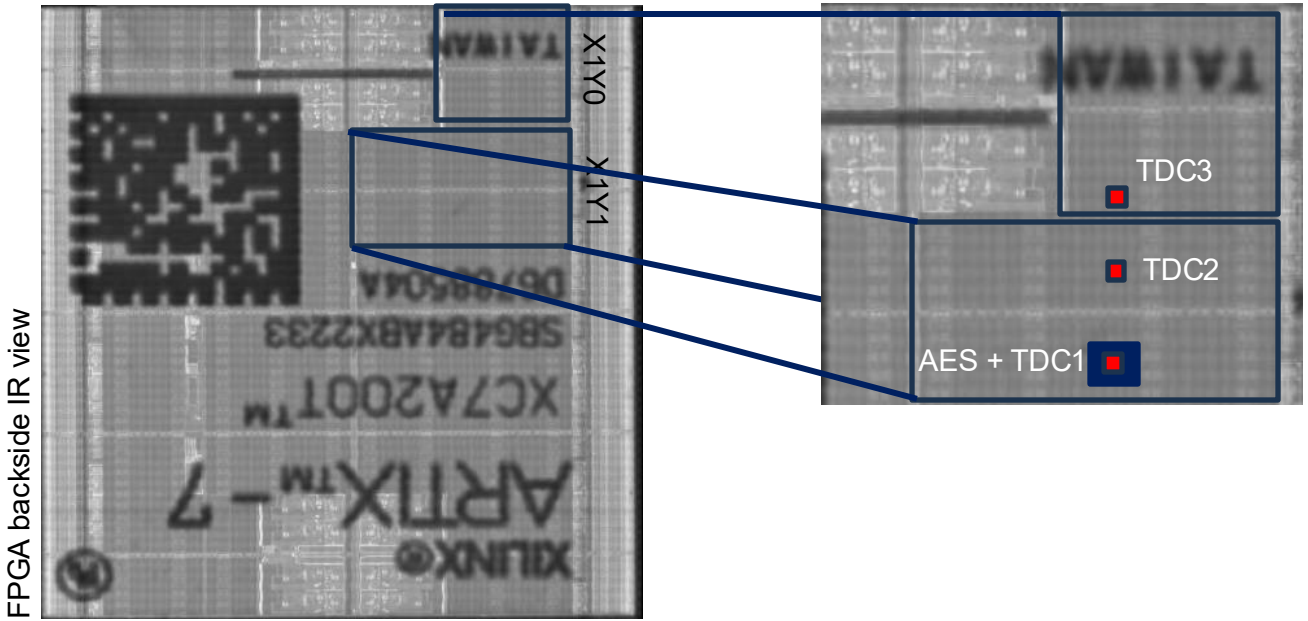
LFI detection sensors

- TDC-based sensor – Universal fault detection sensor?
  - ✓ Ability to detect LFI/EMFI/voltage/temperature/frequency stress
  - ✓ Detection mechanism → 2-step mechanism



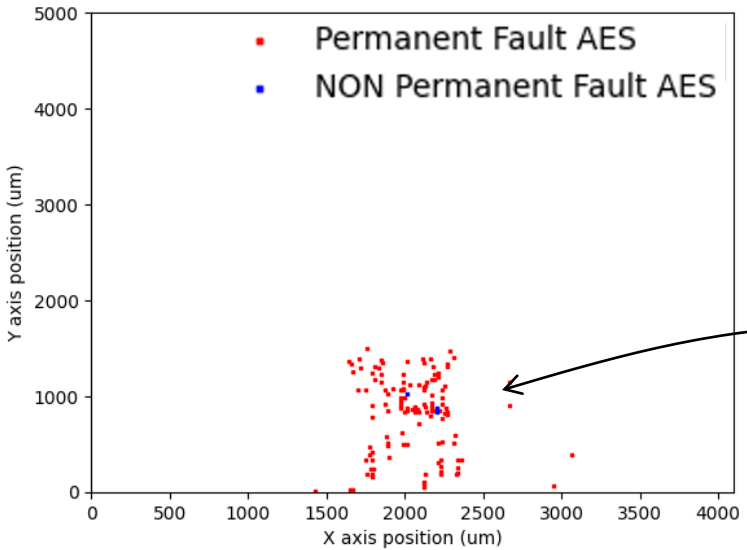
LFI detection sensors

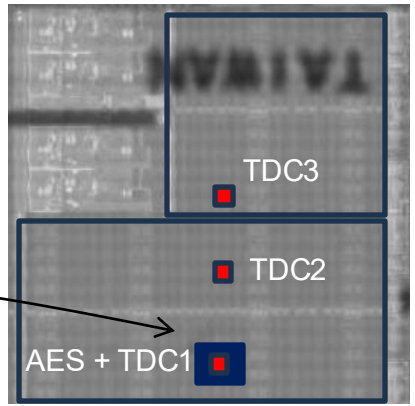
- TDC-based sensor – Tested design
  - ✓ FPGA: AES + 3 TDC sensors



LFI detection sensors

- TDC-based sensor – LFI experiments
  - ✓ Fault injection (AES)
  - ✓ Laser FI threshold 20 ns, 1.3 W, 5 µm ø, 1,064nm

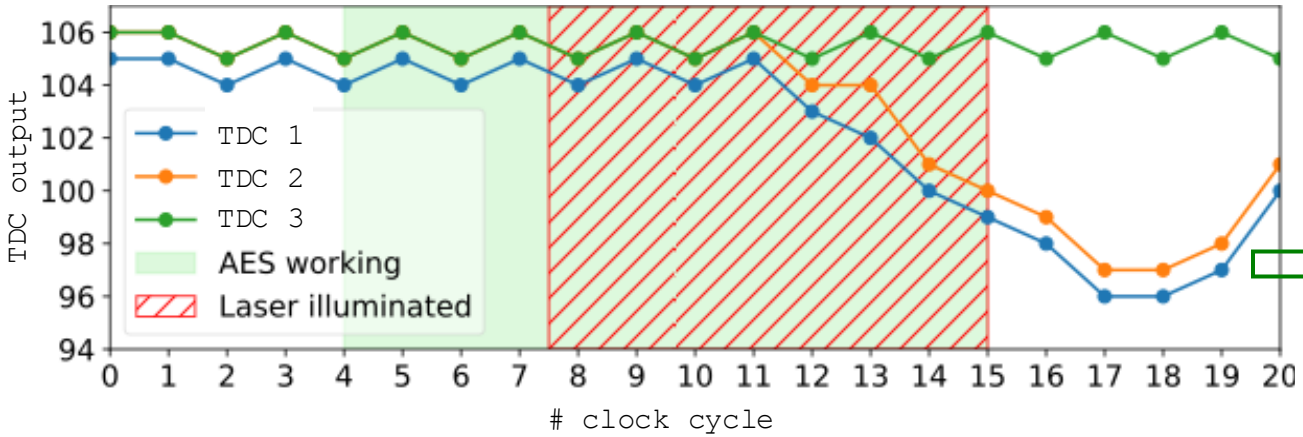




LFI exp. area

LFI detection sensors

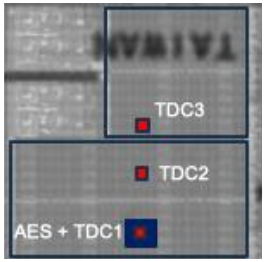
- TDC-based sensor – LFI experiments
  - ✓ Fault Detection (TDC sensor)
  - ✓ Laser parameters 150 ns, 1.6 W, 5 µm ø, on AES → significant effect on TDC 1 & 2



Fault detection

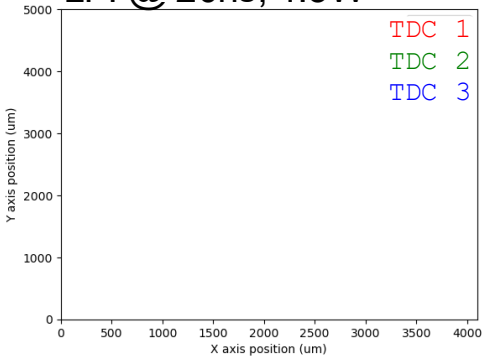
LFI detection sensors

- TDC-based sensor – LFI experiments
  - ✓ Fault Detection (all 3 TDC sensors)
  - → No LFI at 20ns laser pulse
  - → Good LFI detection at 150ns

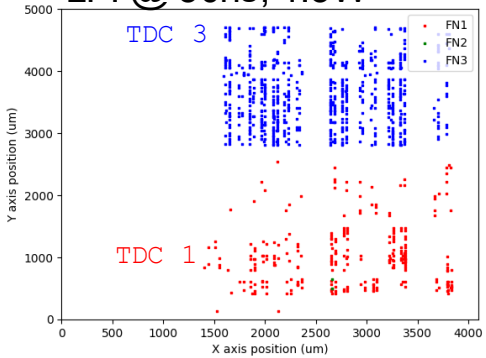


LFI exp. area

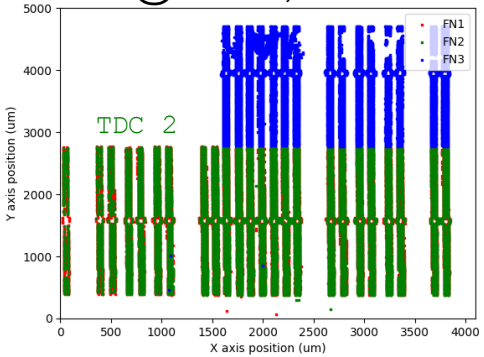
LFI @ 20ns, 1.3W



LFI @ 50ns, 1.3W



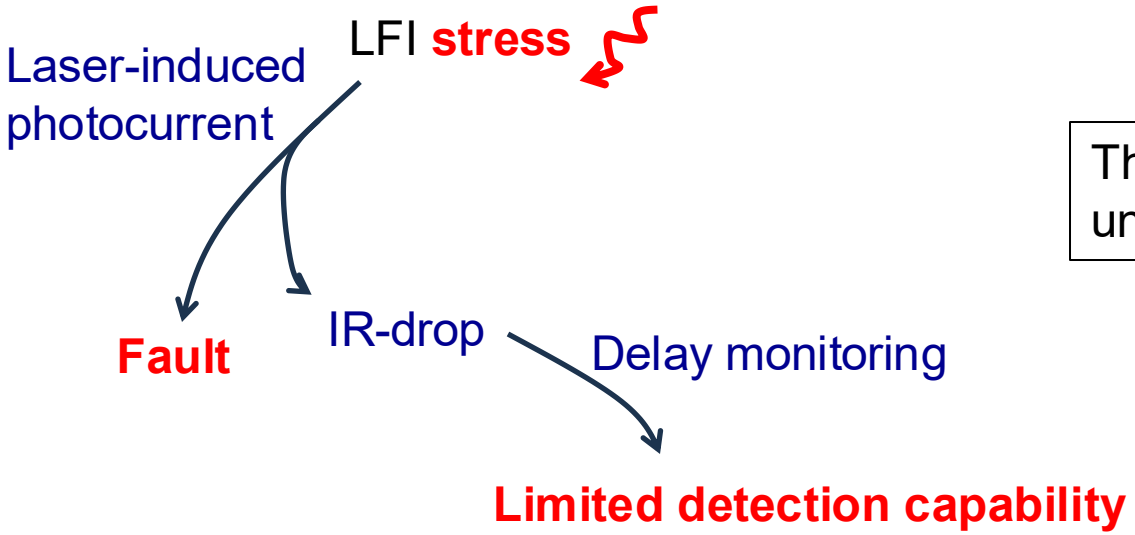
LFI @ 150ns, 1.3W



LFI detection sensors

- TDC-based sensor – Discussion
  - ✓ 75% detection rate at 150ns laser pulse duration (for AES transient faults)
  - ✓ 0% detection at 20ns,which is above the FI threshold

→ Using a 2-step detection mechanism limits sensor detection capability



This questions the idea of a universal sensor

Monitoring FIA with Sensors – Lessons Learned

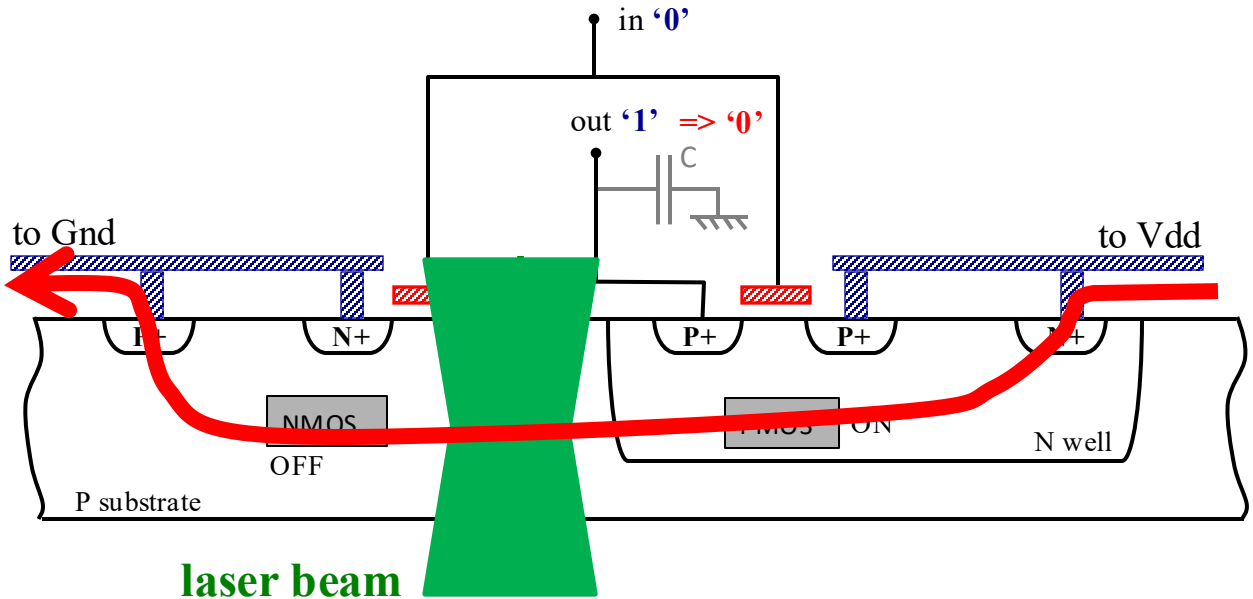
- Monitoring FIA with digital sensors – basics/principles
- Fault Injection Attacks
- EMFI detection sensors

- LFI detection sensors
  - LFI mechanism
  - TDC-based sensor
  - BBICS Bulk Built-In Current Sensor

- Conclusion

LFI detection sensors

- Bulk Built-In Current Sensor, BBICS – Principle
  - ✓ Monitoring of laser-induced bulk currents which is ~0 in nominal condition
  - ✓ Large Vdd to Gnd current component



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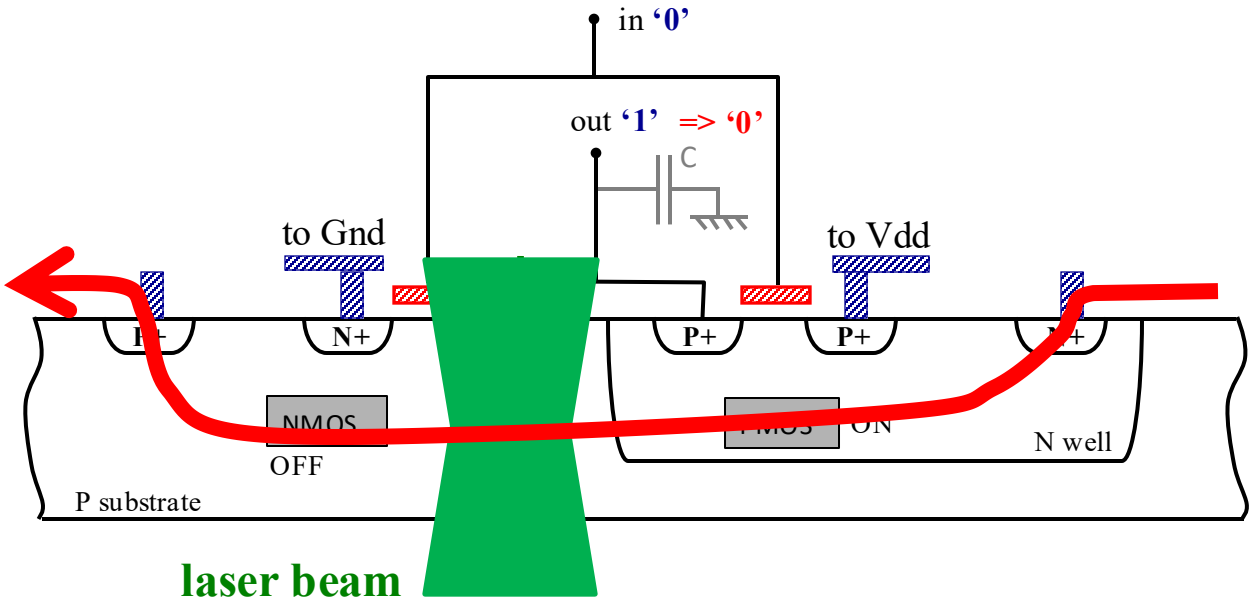
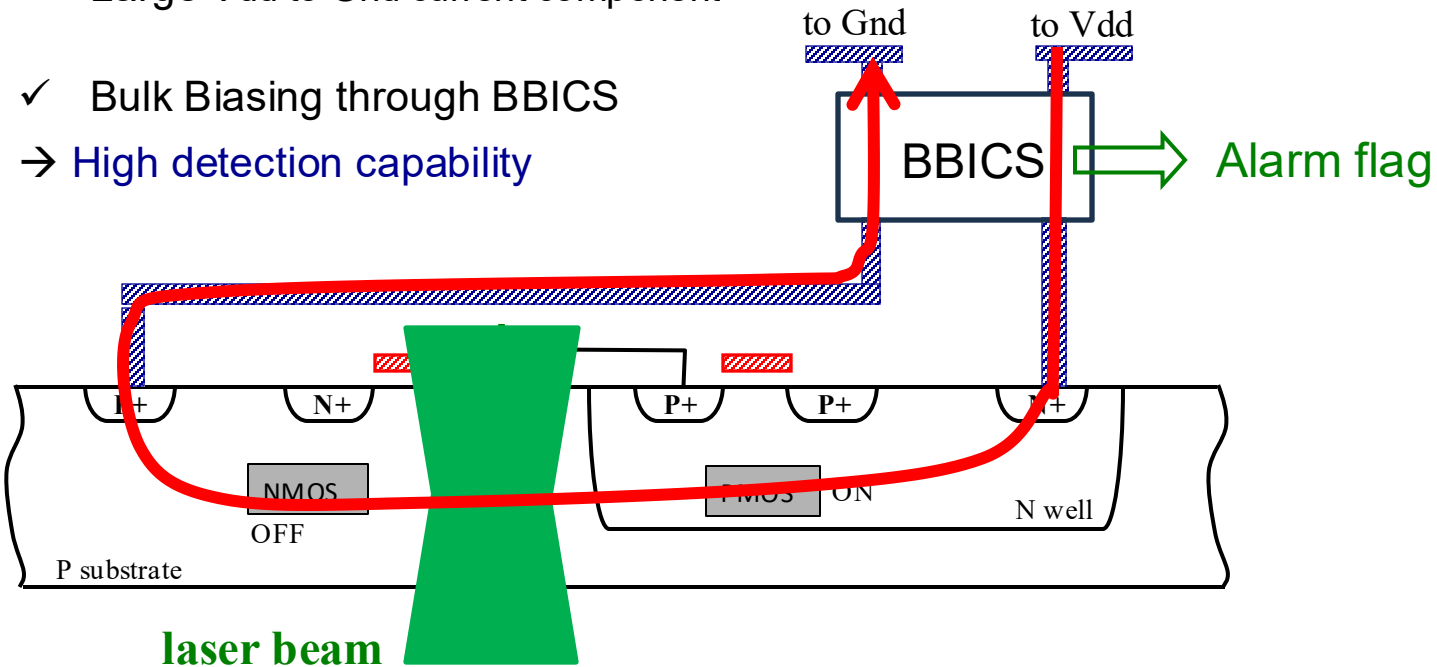


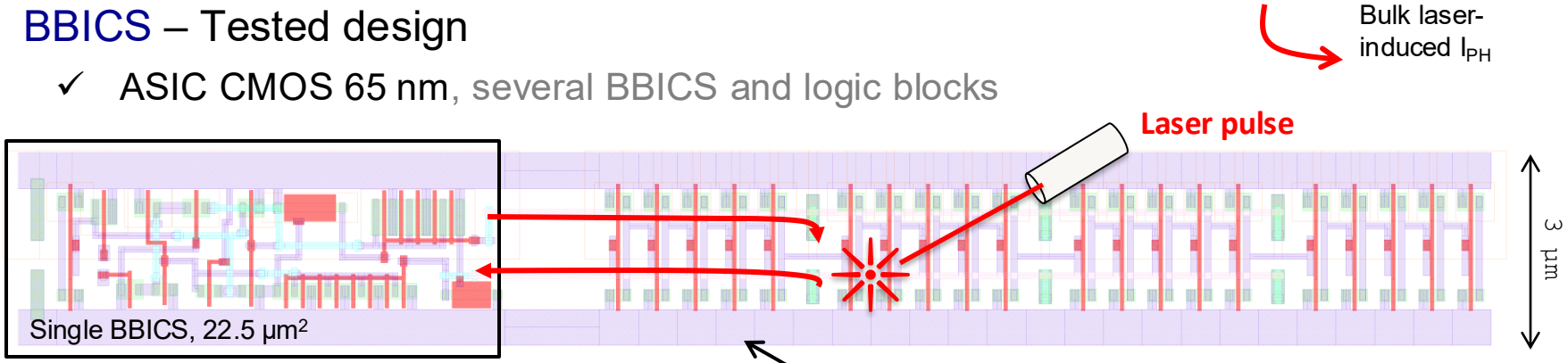
LFI detection sensors

- Bulk Built-In Current Sensor, BBICS – Principle
  - ✓ Monitoring of laser-induced bulk currents which is ~0 in nominal condition
  - ✓ Large Vdd to Gnd current component
  - ✓ Bulk Biasing through BBICS
  - → High detection capability



LFI detection sensors

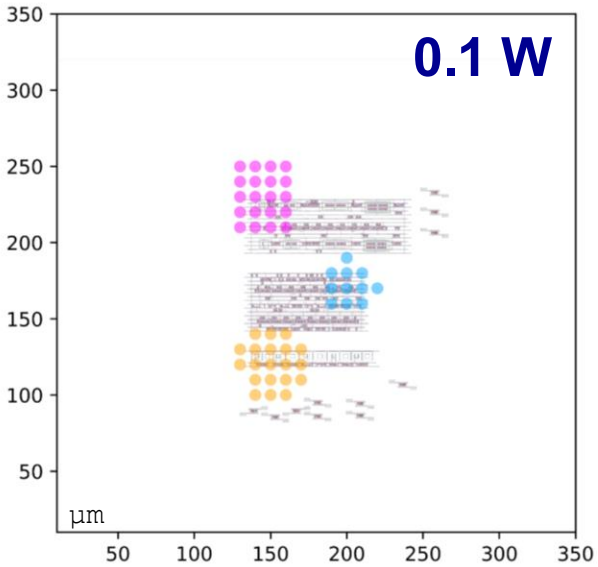
- BBICS – Tested design
  - ✓ ASIC CMOS 65 nm, several BBICS and logic blocks

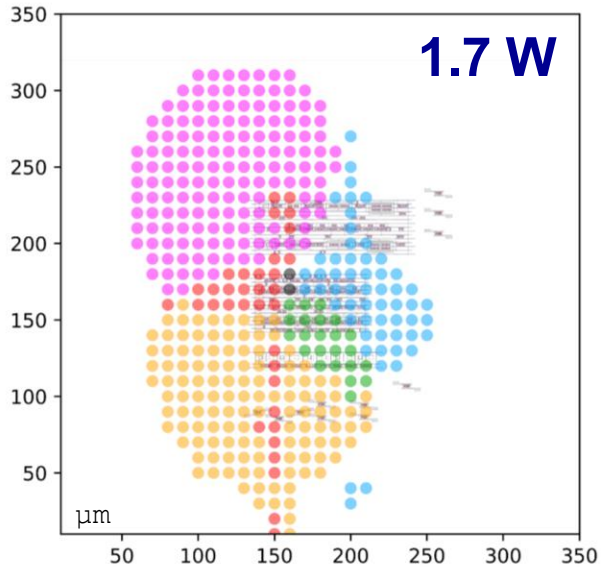


JM Dutertre et al., Improving the ability of bulk built-in current sensors to detect single event effects by using triple-well CMOS, MR 2014

LFI detection sensors

- BBICS – LFI exp.
  - ✓ Laser Fault Injection threshold: **1.9 W** at 50 ns, 5 µm ø, 1,064 nm (DFF bit flip)
  - ✓ LFI detection 50 ns, 5 µm ø, 1,064 nm





LFI detection sensors

- BBICS – LFI exp.
  - ✓ Laser Fault Injection threshold: **1.9 W** at 50 ns, 5 µm ø, 1,064 nm (DFF bit flip)
  - ✓ LFI detection 50 ns, 1,064 nm

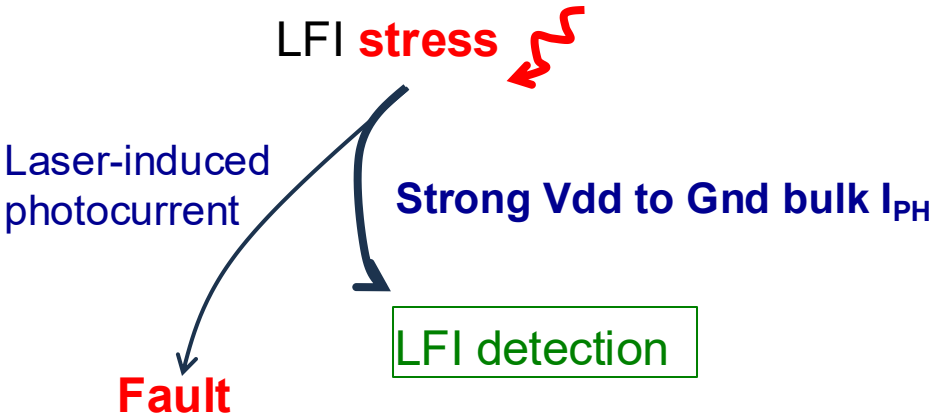
Laser spot diameter	Fault threshold	Detection area at FIA threshold	Detection area at half FIA threshold
5 µm	1.9 W	1,800 µm2 1.9W	950 µm2 0.95W
1 µm	1.7 W	900 µm2 1.7W	600 µm2 0.85W

Single BBICS area 22.5 μm^2

LFI detection sensors

- BBICS – Discussion
  - ✓ Fully efficient at detecting LFI attacks
  - ✓ Based on a sound detection mechanism

Matsuda et al., A 286 f2/cell distributed bulk-current sensor and secure flush code eraser against laser fault injection attack on cryptographic processor, IEEE JSSC 2018



Monitoring FIA with Sensors – Lessons Learned

- Monitoring FIA with digital sensors – basics/principles
- Fault Injection Attacks
- EMFI detection sensors
- LFI detection sensors

- Conclusion

Monitoring FIA with Sensors – Lessons Learned

- Conclusion – A few advices

- Test, test, and test again
  - ✓ There is always something to be forgotten …

- Design a sensor with a detection mechanism matching that on the FIA it is supposed to detect
  - ✓ EMFI and LFI belongs to two distinct FIA families
  - ✓ There is (to date) no fully efficient universal detection sensor

Monitoring FIA with Sensors – Lessons Learned

- Conclusion – A few advices

- Delay-based sensors are good at monitoring stress-induced timing constraint violation
  - ✓ EMFI + T° stress + Voltage & clock glitches
- LFI detection sensors
  - ✓ BBICS work well
  - ✓ Delay-based sensors may miss many LFI

- FIA can be (very) efficiently monitored and detected
  - ✓ To be used as a 1st line of defense (no warranty of 100% efficiency)

Monitoring FIA with Sensors – Lessons Learned

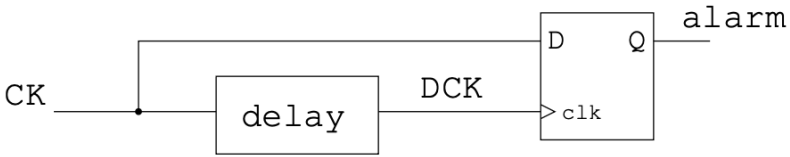
- Conclusion – One last warning

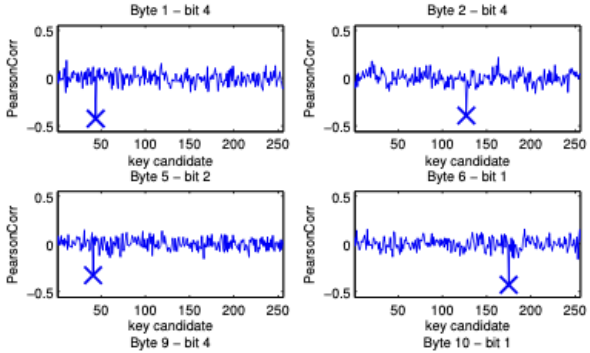
- Delay-based sensors are also used to conduct remote SCA attacks

→ J. Gravellier et al., Remote side-channel attacks on heterogeneous SoC, Cardis 2019

- Delay-based sensor successfully used to retrieve the secret key of the AES crypto-accelerator it was monitoring against FIA (FPGA)

→ L. Zussa, Evidence of an information leakage between logically independent blocks, CS2 2015





Contact:
dutertre@emse.fr

Equipe Commune Systèmes et Architectures Sécurisées
Mines Saint-Etienne, CEA, Leti, Centre CMP
13541 Gardanne FRANCE